19-3438; Rev 0; 10/04

EVALUATION KIT AVAILABLE

EEPROM-Programmable, Hex/Quad, Power-Supply Sequencers/Supervisors

General Description

The MAX6874/MAX6875 EEPROM-configurable, multivoltage supply sequencers/supervisors monitor several voltage detector inputs and general-purpose logic inputs, and provide programmable open-drain outputs for highly configurable power-supply sequencing applications. The MAX6874 provides six voltage monitor inputs, four general-purpose inputs, and eight programmable open-drain outputs. The MAX6875 provides four voltage monitor inputs, three general-purpose inputs, and five programmable open-drain outputs. Manual reset and margin disable inputs provide additional flexibility.

All voltage detectors offer configurable thresholds for undervoltage detection. One high-voltage input (IN1) provides detector threshold voltages from +2.5V to +13.2V in 50mV increments, or from +1.25V to +7.625V in 25mV increments. A second positive input (IN2) provides detector threshold voltages from +2.5V to +5.5V in 50mV increments, or from +1.25V to +3.05V in 25mV increments. Positive inputs (IN3–IN6) provide detector threshold voltages from +1V to +5.5V in 20mV increments, or from +0.5V to +3.05V in 10mV increments.

Programmable output stages control power-supply sequencing or system resets/interrupts. Program the open-drain outputs as active-high or active-low. Programmable timing delay blocks configure each output to wait between 25µs and 1600ms before deasserting.

An SMBus™/I²C-compatible serial data interface programs and communicates with the configuration EEPROM, the configuration registers, and the internal 4kb user EEPROM of the MAX6874/MAX6875.

The MAX6874/MAX6875 are available in a 7mm x 7mm x 0.8mm 32-pin thin QFN package and operate over the extended temperature range (-40°C to +85°C).

Applications

Telecommunications/Central Office Systems
Networking Systems
Servers/Workstations
Base Stations
Storage Equipment
Multimicroprocessor/Voltage Systems

Features

- **Six (MAX6874) or Four (MAX6875) Configurable Input Voltage Detectors**
  - **One High Voltage Input (+1.25V to +7.625V or +2.5V to +13.2V Thresholds)**
  - **One Voltage Input (+1.25V to +3.05V or +2.5V to +5.5V)**
  - **Four (MAX6874) or Two (MAX6875) Positive Voltage Inputs (+0.5V to +3.05V or +1V to +5.5V)**
- **Four (MAX6874) or Three (MAX6875) General-Purpose Logic Inputs**
- **Two Configurable Watchdog Timers**
- **Eight (MAX6874) or Five (MAX6875) Programmable Open-Drain Outputs**
  - **Active-High or Active-Low**
  - **Timing Delays from 25µs to 1600ms**
- **Margining Disable and Manual Reset Controls**
- **4kb Internal User EEPROM**
  - **Endurance: 100,000 Erase/Write Cycles**
  - **Data Retention: 10 Years**
- **I²C/SMBus-Compatible Serial Configuration/Communication Interface**
- **±1% Threshold Accuracy**

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	PKG CODE
MAX6874 ETJ	-40°C to +85°C	32 Thin QFN	T3277-2
MAX6875 ETJ	-40°C to +85°C	32 Thin QFN	T3277-2

SMBus is a trademark of Intel Corp.

Pin Configurations, Typical Operating Circuit, and Selector Guide appear at end of data sheet.

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ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND)
IN2–IN6, ABP, SDA, SCL, A0, A1,
GPI1–GPI4, $\overline{MR}$, $\overline{MARGIN}$, PO5–PO8
(MAX6874), PO3–PO5 (MAX6875).....-0.3V to +6V
IN1, PO1–PO4 (MAX6874), PO1–PO2 (MAX6875)...-0.3V to +14V
DBP .....-0.3V to +3V
Input/Output Current (all pins).....±20mA

Continuous Power Dissipation (T_A = +70°C)
32-Pin 7mm x 7mm Thin QFN
(derate 33.3mW/°C above +70°C).....2667mW
Operating Temperature Range .....-40°C to +85°C
Maximum Junction Temperature .....+150°C
Storage Temperature Range .....-65°C to +150°C
Lead Temperature (soldering, 10s) .....+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{IN1} = +6.5V to +13.2V, V_{IN2}–V_{IN6} = +2.7V to +5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Operating Voltage Range (Note 3)	V_{IN1}	Voltage on IN1 to ensure the device is fully operational, IN3–IN6 = GND		4.0		13.2	V
	V_{IN3} to V_{IN5}	Voltage on any one of IN3–IN5 to ensure the device is fully operational, IN1 = GND		2.7		5.5	
IN1 Supply Voltage (Note 3)	V_{IN1P}	Minimum voltage on IN1 to guarantee that the device is powered through IN1				6.5	V
Undervoltage Lockout	V_{UVLO}	Minimum voltage on one of IN3–IN5 to guarantee the device is EEPROM configured.				2.5	V
Supply Current	I_{CC}	V_{IN1} = +13.2V, IN2–IN6 = GND, no load			1.2	1.5	mA
		Writing to configuration registers or EEPROM, no load			1.3	2	mA
Threshold Range	V_{TH}	V_{IN1} (50mV increments)		2.5		13.2	V
		V_{IN1} (25mV increments)		1.250		7.625	
		V_{IN2} (50mV increments)		2.50		5.5	
		V_{IN2} (25mV increments)		1.250		3.05	
		V_{IN3}–V_{IN6} (20mV increments)		1.0		5.5	
		V_{IN3}–V_{IN6} (10mV increments)		0.50		3.05	
Threshold Accuracy		IN1–IN6, $V_{IN\_}$ falling	T_A = +25°C	-1.0		+1.0	%
			T_A = -40°C to +85°C	-1.5		+1.5	
Threshold Hysteresis	$V_{TH-HYST}$				0.3		% V_{TH}
Reset Threshold Temperature Coefficient	ΔV_{TH}/°C				10		ppm/°C
Threshold-Voltage Differential Nonlinearity	V_{TH} DNL			-1		+1	LSB

ELECTRICAL CHARACTERISTICS (continued)

(V_{IN1} = +6.5V to +13.2V, V_{IN2}–V_{IN6} = +2.7V to +5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
IN1 Input Leakage Current	I_{LIN1}	For V_{IN1} < the highest of V_{IN3}–V_{IN5}			100	140	µA
IN2 Input Impedance	R_{IN2}			160	230	320	kΩ
IN3–IN6 Input Impedance	R_{IN3} to R_{IN6}	V_{IN1} > 6.5V		70	100	145	kΩ
Power-Up Delay	t_{PU}	$V_{ABP} \geq V_{UVLO}$				3.5	ms
IN_ to PO_ Delay	t_{DPO}	$V_{IN\_}$ falling or rising, 100mV overdrive			25		µs
PO_ Timeout Period	t_{RP}	Register contents (Table 16)	000		25		µs
			001	1.406	1.5625	1.719	ms
			010	5.625	6.25	6.875	
			011	22.5	25	27.5	
			100	45	50	55	
			101	180	200	220	
			110	360	400	440	
			111	1440	1600	1760	
PO1–PO4 (MAX6874), PO1–PO2 (MAX6875) Output Low (Note 3)	V_{OL}	$V_{ABP} \geq$ +2.5V, I_{SINK} = 500µA				0.3	V
		$V_{ABP} \geq$ +4.0V, I_{SINK} = 2mA				0.4	
PO5–PO8 (MAX6874), PO3–PO5 (MAX6875) Output Low (Note 3)	V_{OL}	$V_{ABP} \geq$ +2.5V, I_{SINK} = 1mA				0.3	V
		$V_{ABP} \geq$ +4.0V, I_{SINK} = 4mA				0.4	
PO1–PO8 Output Initial Pulldown Current	I_{PD}	$V_{ABP} \leq V_{UVLO}$, $V_{PO\_}$ = 0.8V			10	40	µA
PO1–PO8 Output Open-Drain Leakage Current	I_{LKG}	Output high impedance		-1		+1	µA

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ELECTRICAL CHARACTERISTICS (continued)

(V_{IN1} = +6.5V to +13.2V, V_{IN2}–V_{IN6} = +2.7V to +5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
$\overline{MR}$, $\overline{MARGIN}$, GPI_ Input Voltage	V_{IL}					0.8	V
	V_{IH}			1.4			
$\overline{MR}$ Input Pulse Width	t_{MR}			1			µs
$\overline{MR}$ Glitch Rejection					100		ns
$\overline{MR}$ to PO_ Delay	t_{DMR}				2		µs
$\overline{MR}$ to V_{DBP} Pullup Current	I_{MR}	$V_{\overline{MR}}$ = +1.4V		5	10	15	µA
$\overline{MARGIN}$ to V_{DBP} Pullup Current	I_{MARGIN}	$V_{\overline{MARGIN}}$ = +1.4V		5	10	15	µA
GPI_ to PO_ Delay	$t_{DGPI\_}$				200		ns
GPI_ Pulldown Current	$I_{GPI\_}$	$V_{GPI\_}$ = +0.8V		5	10	15	µA
Watchdog Input Pulse Width	t_{WDI}	GPI_ configured as a watchdog input		50			ns
Watchdog Timeout Period	t_{WD}	Register Contents (Table 19)	000	5.625	6.25	6.875	ms
			001	22.5	25	27.5	
			010	90	100	110	
			011	360	400	440	
			100	1.44	1.6	1.76	s
			101	5.76	6.4	7.04	
			110	23.04	25.6	28.16	
			111	92.16	102.4	112.64	
SERIAL INTERFACE LOGIC (SDA, SCL, A0, A1)							
Logic-Input Low Voltage	V_{IL}					0.8	V
Logic-Input High Voltage	V_{IH}			2.0			V
Input Leakage Current	I_{LKG}			-1		+1	µA
Output Voltage Low	V_{OL}	I_{SINK} = 3mA				0.4	V
Input/Output Capacitance	$C_{I/O}$				10		pF

TIMING CHARACTERISTICS

(IN1 = GND, V_{IN2}–V_{IN6} = +2.7V to +5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
TIMING CHARACTERISTICS (Figure 2)						
Serial Clock Frequency	f_{SCL}				400	kHz
Clock Low Period	t_{LOW}		1.3			µs
Clock High Period	t_{HIGH}		0.6			µs
Bus-Free Time	t_{BUF}		1.3			µs
START Setup Time	$t_{SU:STA}$		0.6			µs
START Hold Time	$t_{HD:STA}$		0.6			µs
STOP Setup Time	$t_{SU:STO}$		0.6			µs
Data-In Setup Time	$t_{SU:DAT}$		100			ns
Data-In Hold Time	$t_{HD:DAT}$		0		900	ns
Receive SCL/SDA Minimum Rise Time	t_R	(Note 4)		20 + 0.1 x C_{BUS}		ns
Receive SCL/SDA Maximum Rise Time	t_R	(Note 4)		300		ns
Receive SCL/SDA Minimum Fall Time	t_F	(Note 4)		20 + 0.1 x C_{BUS}		ns
Receive SCL/SDA Maximum Fall Time	t_F	(Note 4)		300		ns
Transmit SDA Fall Time	t_F	C_{BUS} = 400pF	20 + 0.1 x C_{BUS}		300	ns
Pulse Width of Spike Suppressed	t_{SP}	(Note 5)		50		ns
EEPROM Byte Write Cycle Time	t_{WR}	(Note 6)			11	ms

Note 1: Specifications guaranteed for the stated global conditions. The device also meets the parameters specified when 0 < V_{IN1} < +6.5V, and at least one of V_{IN3}–V_{IN6} is between +2.7V and +5.5V, while the remaining V_{IN3}–V_{IN6} are between 0 and +5.5V.

Note 2: Device may be supplied from any one of IN_, except IN2 and IN6.

Note 3: The internal supply voltage, measured at ABP, equals the maximum of IN3–IN5 if V_{IN1} = 0, or equals +5.4V if V_{IN1} > +6.5V. For +4V < V_{IN1} < +6.5V and V_{IN3}–V_{IN5} > +2.7V, the input that powers the device cannot be determined.

Note 4: C_{BUS} = total capacitance of one bus line in pF. Rise and fall times are measured between 0.1 x V_{BUS} and 0.9 x V_{BUS}.

Note 5: Input filters on SDA, SCL, A0, and A1 suppress noise spikes < 50ns.

Note 6: An additional cycle is required when writing to configuration memory for the first time.

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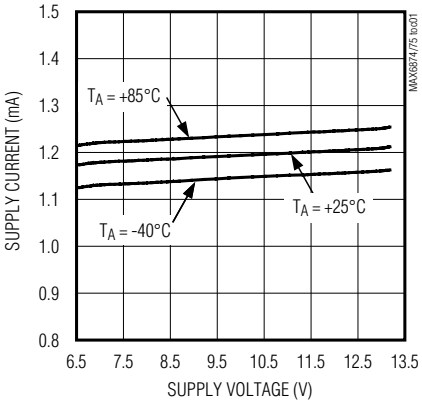
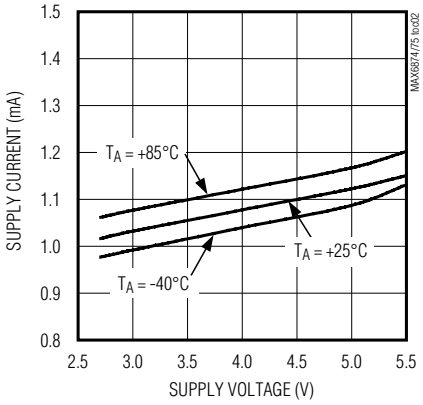
Typical Operating Characteristics

(V_{IN1} = +6.5V to +13.2V, V_{IN2}–V_{IN6} = +2.7V to +5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = +25°C, unless otherwise noted.)

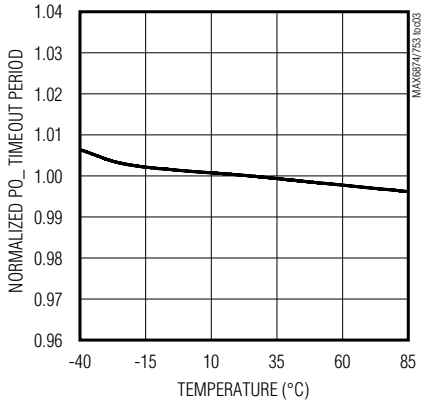
SUPPLY CURRENT vs. SUPPLY VOLTAGE (IN1)



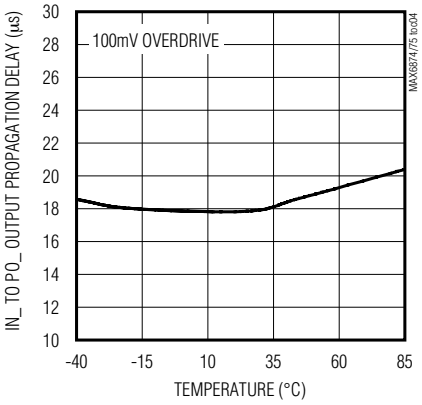
SUPPLY CURRENT vs. SUPPLY VOLTAGE (IN3 TO IN5)



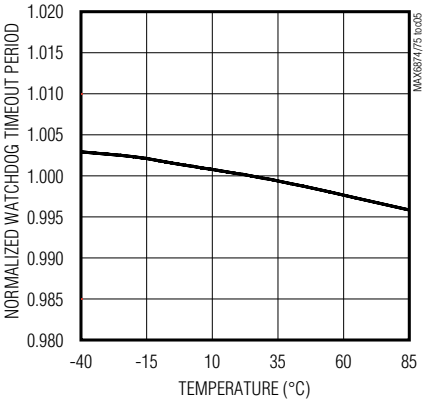
NORMALIZED PO_ TIMEOUT PERIOD vs. TEMPERATURE



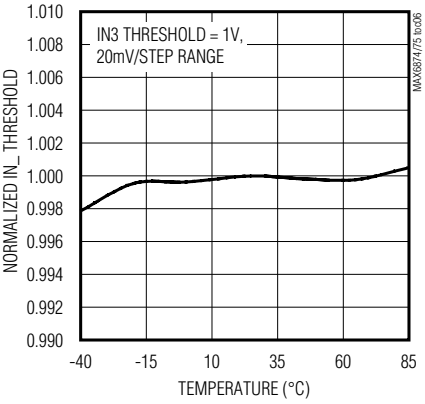
IN_ TO PO_ PROPAGATION DELAY vs. TEMPERATURE



NORMALIZED WATCHDOG TIMEOUT PERIOD vs. TEMPERATURE



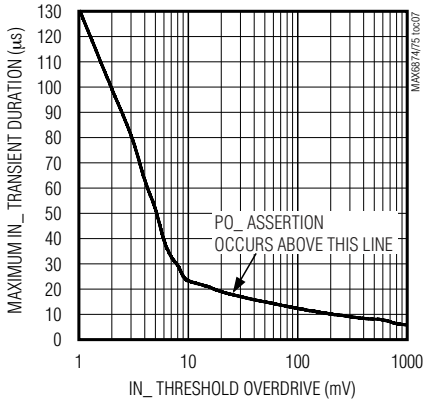
NORMALIZED IN_ THRESHOLD vs. TEMPERATURE



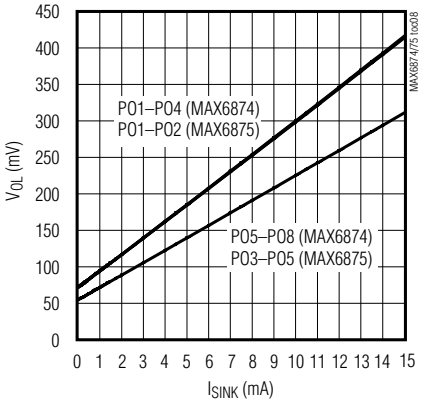
Typical Operating Characteristics (continued)

(V_{IN1} = +6.5V to +13.2V, V_{IN2}–V_{IN6} = +2.7V to +5.5V, GPI_ = GND, $\overline{MARGIN}$ = $\overline{MR}$ = DBP, T_A = +25°C, unless otherwise noted.)

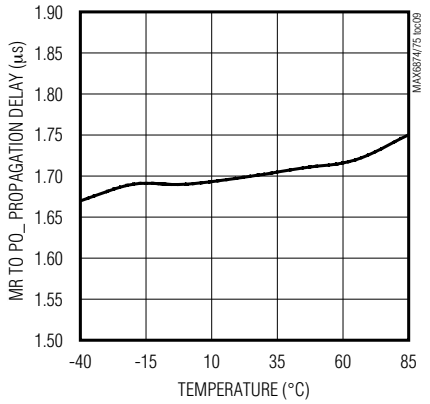
MAXIMUM IN_ TRANSIENT DURATION vs. IN_ THRESHOLD OVERDRIVE



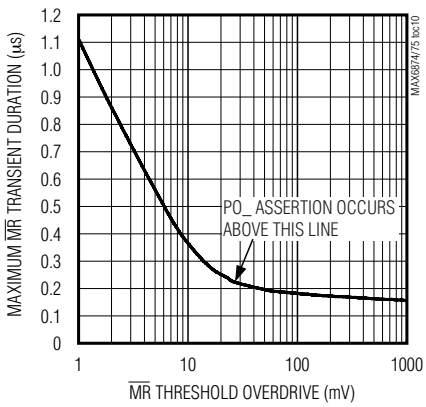
OUTPUT VOLTAGE LOW vs. SINK CURRENT



$\overline{MR}$ TO PO_ PROPAGATION DELAY vs. TEMPERATURE



MAXIMUM $\overline{MR}$ TRANSIENT DURATION vs. $\overline{MR}$ THRESHOLD OVERDRIVE



Pin Description

PIN		NAME	FUNCTION
MAX6874	MAX6875		
1	3	PO2	Programmable Output 2. Configurable active-high or active-low open-drain output. PO2 pulls low with a 10µA internal current sink for +1V < V_{ABP} < V_{UVLO}. PO2 assumes its programmed conditional output state when ABP exceeds UVLO.
2	5	PO3	Programmable Output 3. Configurable active-high or active-low open-drain output. PO3 pulls low with a 10µA internal current sink for +1V < V_{ABP} < V_{UVLO}. PO3 assumes its programmed conditional output state when ABP exceeds UVLO.
3	6	PO4	Programmable Output 4. Configurable active-high or active-low open-drain output. PO4 pulls low with a 10µA internal current sink for +1V < V_{ABP} < V_{UVLO}. PO4 assumes its programmed conditional output state when ABP exceeds UVLO.
4	4	GND	Ground
5	7	PO5	Programmable Output 5. Configurable active-high or active-low open-drain output. PO5 pulls low with a 10µA internal current sink for +1V < V_{ABP} < V_{UVLO}. PO5 assumes its programmed conditional output state when ABP exceeds UVLO.
6	—	PO6	Programmable Output 6. Configurable active-high or active-low open-drain output. PO6 pulls low with a 10µA internal current sink for +1V < V_{ABP} < V_{UVLO}. PO6 assumes its programmed conditional output state when ABP exceeds UVLO.
7	—	PO7	Programmable Output 7. Configurable active-high or active-low open-drain output. PO7 pulls low with a 10µA internal current sink for +1V < V_{ABP} < V_{UVLO}. PO7 assumes its programmed conditional output state when ABP exceeds UVLO.
8	—	PO8	Programmable Output 8. Configurable active-high or active-low open-drain output. PO8 pulls low with a 10µA internal current sink for +1V < V_{ABP} < V_{UVLO}. PO8 assumes its programmed conditional output state when ABP exceeds UVLO.
9, 10, 23, 24	1, 8, 9,10, 16, 17, 23–26, 32	N.C.	No Connection. Not internally connected.
11	11	$\overline{MARGIN}$	Margin Input. Drive $\overline{MARGIN}$ low to hold PO_ in their existing states. Leave $\overline{MARGIN}$ unconnected or connect to DBP if unused. $\overline{MARGIN}$ overrides $\overline{MR}$ if both assert at the same time. $\overline{MARGIN}$ is internally pulled up to DBP through a 10µA current source.
12	12	$\overline{MR}$	Manual Reset Input. $\overline{MR}$ to either assert PO_ into a programmed state or to have no effect on PO_ when driving $\overline{MR}$ low (see Table 6). Leave $\overline{MR}$ unconnected or connect to DBP if unused. $\overline{MR}$ is internally pulled up to DBP through a 10µA current source.
13	13	SDA	Serial Data Input/Output (Open-Drain). SDA requires an external pullup resistor.
14	14	SCL	Serial Clock Input. SCL requires an external pullup resistor.
15	15	A0	Address Input 0. Address inputs allow up to four MAX6874 or two MAX6875 connections on one common bus. Connect A0 to GND or to the serial interface power supply.
16	—	A1	Address Input 1 (MAX6874 only). Address inputs allow up to four MAX6874 connections on one common bus. Connect A1 to GND or to the serial interface power supply.

Pin Description (continued)

PIN		NAME	FUNCTION
MAX6874	MAX6875		
17	—	GPI4	General-Purpose Logic Input 4 (MAX6874 Only). An internal 10µA current source pulls GPI4 to GND. Configure GPI4 to control watchdog timer functions or the programmable outputs.
18	18	GPI3	General-Purpose Logic Input 3. An internal 10µA current source pulls GPI3 to GND. Configure GPI3 to control watchdog timer functions or the programmable outputs.
19	19	GPI2	General-Purpose Logic Input 2. An internal 10µA current source pulls GPI2 to GND. Configure GPI2 to control watchdog timer functions or the programmable outputs.
20	20	GPI1	General-Purpose Logic Input 1. An internal 10µA current source pulls GPI1 to GND. Configure GPI1 to control watchdog timer functions or the programmable outputs.
21	21	ABP	Internal Power-Supply Output. Bypass ABP to GND with a 1µF ceramic capacitor. ABP powers the internal circuitry of the MAX6874/MAX6875. Do not use ABP to supply power to external circuitry.
22	22	DBP	Internal Digital Power-Supply Output. Bypass DBP to GND with a 1µF ceramic capacitor. DBP supplies power to the EEPROM memory and the internal logic circuitry. Do not use DBP to supply power to external circuitry.
25	—	IN6	Voltage Input 6. Configure IN6 to detect voltage thresholds between +1V and +5.5V in 20mV increments, or +0.5V to +3.05V in 10mV increments. For improved noise immunity, bypass IN6 to GND with a 0.1µF capacitor installed as close to the device as possible.
26	—	IN5	Voltage Input 5. Configure IN5 to detect voltage thresholds between +1V and +5.5V in 20mV increments, or +0.5V to +3.05V in 10mV increments. For improved noise immunity, bypass IN5 to GND with a 0.1µF capacitor installed as close to the device as possible.
27	27	IN4	Voltage Input 4. Configure IN4 to detect voltage thresholds between +1V and +5.5V in 20mV increments, or +0.5V to +3.05V in 10mV increments. For improved noise immunity, bypass IN4 to GND with a 0.1µF capacitor installed as close to the device as possible.
28	28	IN3	Voltage Input 3. Configure IN3 to detect voltage thresholds between +1V and +5.5V in 20mV increments, or +0.5V to +3.05V in 10mV increments. For improved noise immunity, bypass IN3 to GND with a 0.1µF capacitor installed as close to the device as possible.
29	29	IN2	Voltage Input 2. Configure IN2 to detect voltage thresholds from +2.5V to +5.5V in 50mV increments or +1.25V to +3.05V in 25mV increments. For improved noise immunity, bypass IN2 to GND with a 0.1µF capacitor installed as close to the device as possible.
30	30	IN1	High-Voltage Input 1. Configure IN1 to detect voltage thresholds from +2.5V to +13.2V in 50mV increments or +1.25V to +7.6V in 25mV increments. For improved noise immunity, bypass IN1 to GND with a 0.1µF capacitor installed as close to the device as possible.
31	31	I.C.	Internal Connection. Leave unconnected.
32	2	PO1	Programmable Output 1. Configurable active-high or active-low open-drain output. PO1 pulls low with a 10µA internal current sink for $+1V < V_{ABP} < V_{UVLO}$. PO1 assumes its programmed conditional output state when ABP exceeds UVLO.
—	—	EP	Exposed Paddle. Exposed paddle is internally connected to GND.

EEPROM-Programmable, Hex/Quad, Power-Supply Sequencers/Supervisors

Detailed Description

The MAX6874/MAX6875 EEPROM-configurable, multivoltage supply sequencers/supervisors monitor several voltage detector inputs and general-purpose logic inputs, and feature programmable outputs for highly configurable power-supply sequencing applications. The MAX6874 features six voltage detector inputs, four general-purpose logic inputs, and eight programmable outputs, while the MAX6875 features four voltage detector inputs, three general-purpose logic inputs, and five programmable outputs. Manual reset and margin disable inputs simplify board-level testing during the manufacturing process. The MAX6874/MAX6875 feature an accurate internal 1.25V reference.

All voltage detectors provide configurable thresholds for undervoltage detection. One high-voltage input (IN1) provides detector threshold voltages from +1.25V to +7.625V in 25mV increments or +2.5V to +13.2V in 50mV increments. A positive input (IN2) provides detector threshold voltages from +1.25V to +3.05V in 25mV increments or +2.5V to +5.5V in 50mV increments. Positive inputs (IN3–IN6) provide detector threshold voltages from +0.5V to +3.05V in 10mV increments or +1.0V to +5.5V in 20mV increments.

The host controller communicates with the MAX6874/MAX6875's internal 4kb user EEPROM, configuration EEPROM, and configuration registers through an SMBus/I²C-compatible serial interface (see Figure 1).

Program the open-drain outputs as active-high or active-low. Program each output to assert on any voltage detector input, general-purpose logic input, watchdog timer, manual reset, or other output stages. Programmable timing delay blocks configure each output to wait between 25µs and 1600ms before de-asserting.

The MAX6874/MAX6875 feature a watchdog timer, adding flexibility. Program the watchdog timer to assert one or more programmable outputs. Program the watchdog timer to clear on a combination of one GPI_ input and one programmable output, one of the GPI_ inputs only, or one of the programmable outputs only. The initial and normal watchdog timeout periods are independently programmable from 6.25ms to 102.4s.

A virtual diode-ORing scheme selects the input that powers the MAX6874/MAX6875. The MAX6874/MAX6875 derive power from IN1 if V_{IN1} > +6.5V or from the highest voltage on IN3–IN5 if V_{IN1} < +2.7V. The power source cannot be determined if +4V < V_{IN1} < +6.5V and one of V_{IN3} through V_{IN5} > +2.7V. The programmable outputs maintain the correct programmed logic state for V_{ABP} > V_{UVLO}. One of IN3 through IN5 must be greater than +2.7V or IN1 must be greater than +4V for device operation.

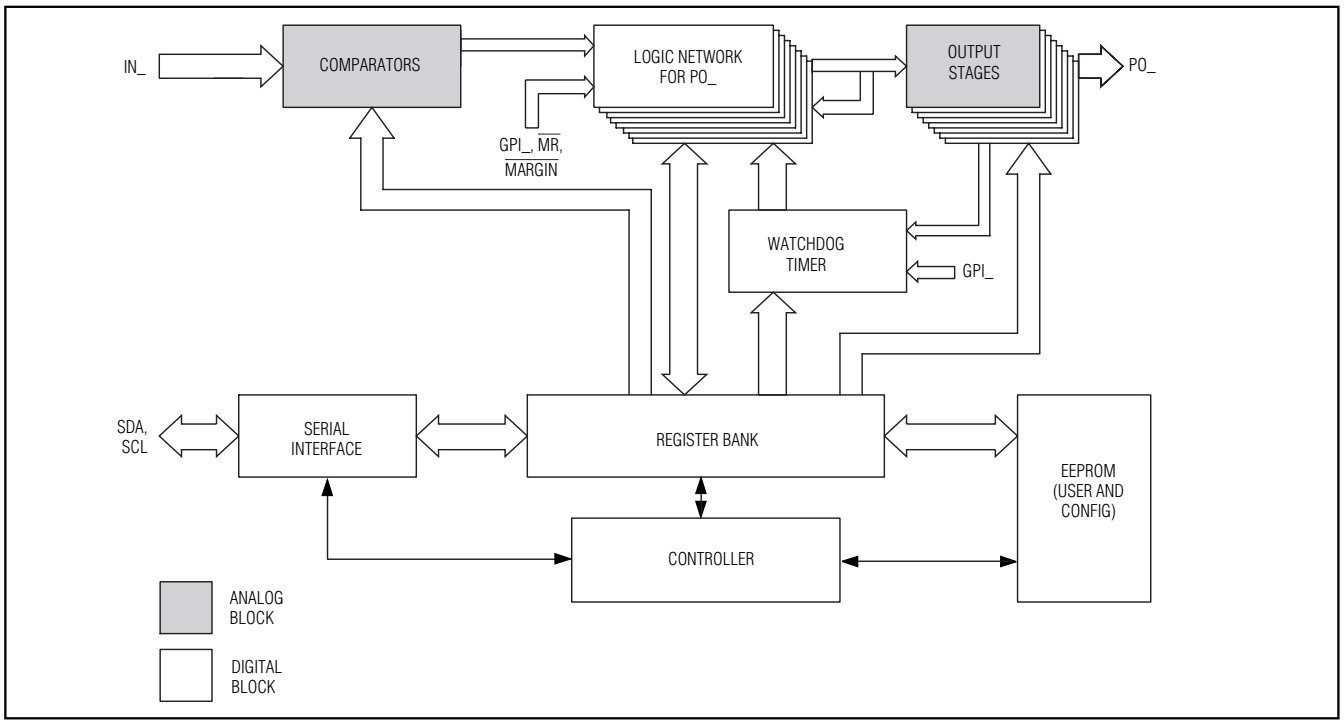
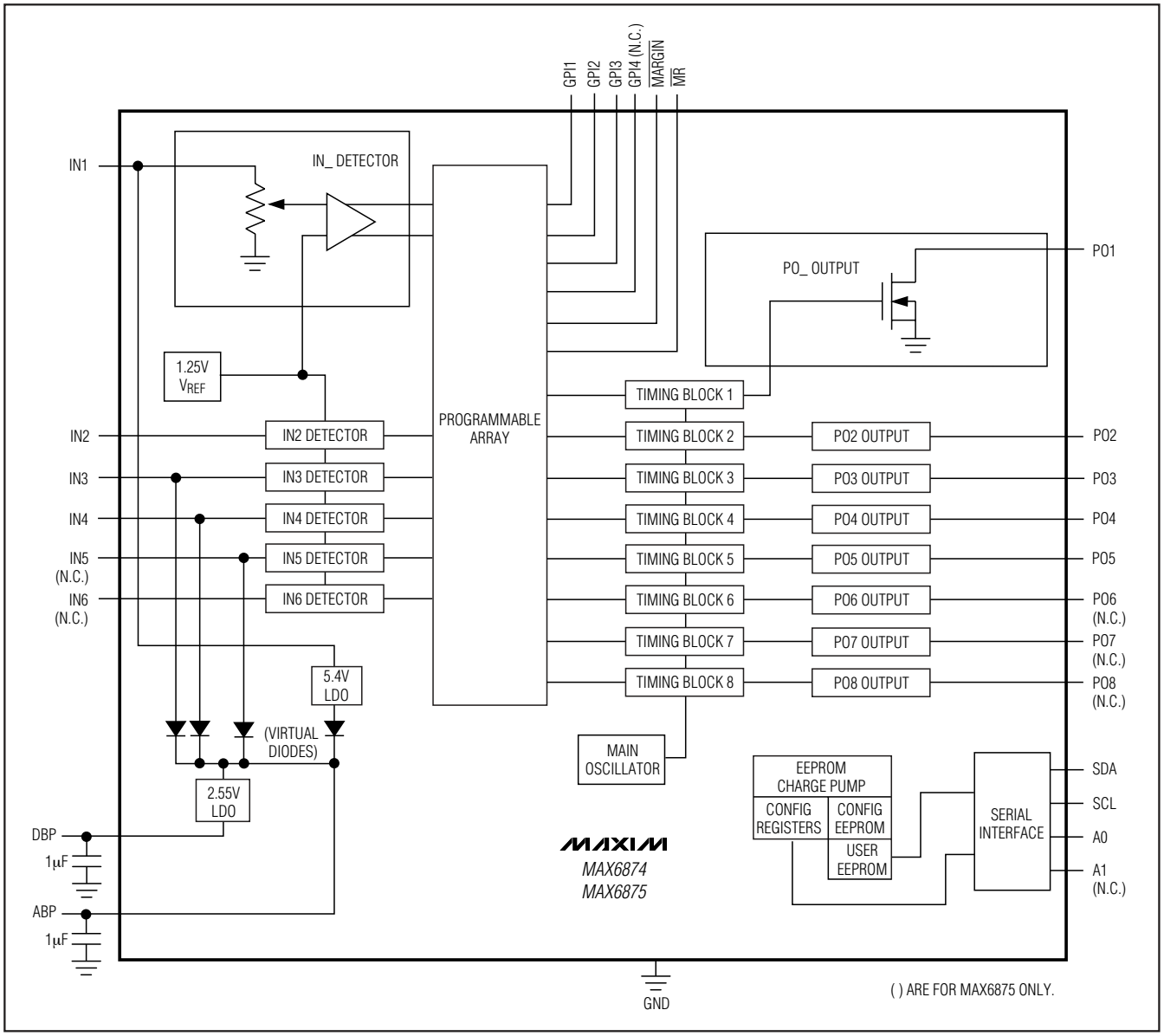


Figure 1. Top-Level Block Diagram

Functional Diagram



EEPROM-Programmable, Hex/Quad, Power-Supply Sequencers/Supervisors

Powering the MAX6874/MAX6875

The MAX6874/MAX6875 derive power from the positive voltage-detector inputs: IN1 or IN3–IN5. A virtual diode-ORing scheme selects the positive input that supplies power to the device (see the *Functional Diagram*). IN1 must be at least +4V or one of IN3–IN5 (MAX6874)/IN3–IN4 (MAX6875) must be at least +2.7V to ensure device operation. An internal LDO regulates IN1 down to +5.4V.

The highest input voltage on IN3–IN5 (MAX6874)/IN3–IN4 (MAX6875) supplies power to the device, unless $V_{IN1} \geq +6.5V$, in which case IN1 supplies power to the device. For $+4V < V_{IN1} < +6.5V$ and one of V_{IN3} through $V_{IN5} > +2.7V$, the input power source cannot be determined due to the dropout voltage of the LDO. Internal hysteresis ensures that the supply input that initially powered the device continues to power the device when multiple input voltages are within 50mV of each other.

ABP powers the analog circuitry; bypass ABP to GND with a 1µF ceramic capacitor installed as close to the device as possible. The internal supply voltage, measured at ABP, equals the maximum of IN3–IN5 (MAX6874)/IN3–IN4 (MAX6875) if $V_{IN1} = 0$, or equals +5.4V when $V_{IN1} > +6.5V$. Do not use ABP to provide power to external circuitry.

The MAX6874/MAX6875 also generate a digital supply voltage (DBP) for the internal logic circuitry and the EEPROM; bypass DBP to GND with a 1µF ceramic capacitor installed as close to the device as possible. The nominal DBP output voltage is +2.55V. Do not use DBP to provide power to external circuitry.

Inputs

The MAX6874/MAX6875 contain multiple logic and voltage-detector inputs. Table 1 summarizes these various inputs.

Set the threshold voltages for each voltage-detector input with registers 00h–05h. Each threshold voltage is an undervoltage threshold. Set the threshold range for each voltage detector with register 0Dh.

Table 1. Programmable Features

FEATURE	DESCRIPTION
High-Voltage Input (IN1)	• Undervoltage threshold • +2.5V to +13.2V threshold in 50mV increments • +1.25V to +7.625V threshold in 25mV increments
Voltage Input (IN2)	• Undervoltage threshold • +2.5V to +5.5V threshold in 50mV increments • +1.25V to +3.05V threshold in 25mV increments
Voltage Input IN3–IN6 (MAX6874), IN3–IN4 (MAX6875)	• Undervoltage threshold • +1V to +5.5V threshold in 20mV increments • +0.5V to +3.05V threshold in 10mV increments
Programmable Outputs PO1–PO8 (MAX6874), PO1–PO5 (MAX6875)	• Active high or active low • Open-drain output • Dependent on $\overline{MR}$, $\overline{MARGIN}$, IN_, GPI1–GPI4 , WD, and/or PO_ • Programmable timeout periods of 25µs, 1.5625ms, 6.25ms, 25ms, 50ms, 200ms, 400ms, or 1.6s
General-Purpose Logic Inputs, GPI1–GPI4 (MAX6874), GPI1–GPI3 (MAX6875)	• Active-high or active-low logic levels • Configure GPI_ as inputs to watchdog timers or programmable output stages
Watchdog Timer	• Clear dependent on any combination of one GPI_ input and one programmable output, a GPI_ input only, or a programmable output only • Initial watchdog timeout period of 6.25ms, 25ms, 100ms, 400ms, 1.6s, 6.4s, 25.6s, or 102.4s • Normal watchdog timeout period of 6.25ms, 25ms, 100ms, 400ms, 1.6s, 6.4s, 25.6s, or 102.4s • Watchdog enable/disable

Table 1. Programmable Features (continued)

FEATURE	DESCRIPTION
Manual Reset Input ($\overline{MR}$)	• Forces PO_ into the active output state when $\overline{MR}$ = GND • PO_ deassert after $\overline{MR}$ releases high and the PO_ timeout period expires • PO_ cannot be a function of $\overline{MR}$ only
Write Disable	• Locks user EEPROM based on PO_
Configuration Lock	• Locks configuration EEPROM

High-Voltage Input (IN1)

IN1 offers threshold voltages of +2.5V to +13.2V in 50mV increments, or +1.25V to +7.625V in 25mV increments. Use the following equations to set the threshold voltages for IN1:

$$x = \frac{V_{TH} - 2.5V}{0.05V} \text{ for } +2.5V \text{ to } +13.2V \text{ range}$$

$$x = \frac{V_{TH} - 1.25V}{0.025V} \text{ for } +1.25V \text{ to } +7.625V \text{ range}$$

where V_{TH} is the desired threshold voltage and x is the decimal code for the desired threshold (Table 2). For the +2.5V to +13.2V range, x must equal 214 or less, otherwise the threshold exceeds the maximum operating voltage of IN1.

IN2

IN2 offers thresholds from +2.5V to +5.5V in 50mV increments, or +1.25V to +3.05V in 25mV increments. Use the following equations to set the threshold voltages for IN2:

$$x = \frac{V_{TH} - 2.5V}{0.05V} \text{ for } +2.5V \text{ to } +5.5V \text{ range}$$

$$x = \frac{V_{TH} - 1.25V}{0.025V} \text{ for } +1.25V \text{ to } +3.05V \text{ range}$$

where V_{TH} is the desired threshold voltage and x is the decimal code for the desired threshold (Table 3).

For the +2.5V to +5.5V range, x must equal 60 or less, otherwise the threshold exceeds the maximum operating voltage of IN2. For the +1V to +3.05V range, x must equal 72 or less.

IN3–IN6

IN3–IN6 offer positive voltage detectors monitor voltages from +1V to +5.5V in 20mV increments, or +0.5V to +3.05V in 10mV increments. Use the following equations to set the threshold voltages for IN_:

$$x = \frac{V_{TH} - 1V}{0.02V} \text{ for } +1V \text{ to } +5.5V \text{ range}$$

$$x = \frac{V_{TH} - 0.5V}{0.01V} \text{ for } +0.5V \text{ to } +3.05V \text{ range}$$

where V_{TH} is the desired threshold voltage and x is the decimal code for the desired threshold (Table 4). For the +1V to +5.5V range, x must equal 225 or less, otherwise the threshold exceeds the maximum operating voltage of IN3–IN6.

Table 2. IN1 Threshold Settings

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
00h	8000h	[7:0]	IN1 detector threshold (V1) (see equations in the *High-Voltage Input (IN1)* section).
0Dh	800Dh	[0]	IN1 range selection: 0 = 2.5V to 13.2V range in 50mV increments. 1 = 1.25V to 7.625V range in 25mV increments.

Table 3. IN2 Threshold Settings

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
01h	8001h	[7:0]	IN2 detector threshold (V2) (see equations in the *IN2* section).
0Dh	800Dh	[7:6]	IN2 range selection: 00 = Not used. 01 = Not used. 10 = +2.5V to +5.5V range in 50mV increments. 11 = +1.25V to +3.05V range in 25mV increments.

Table 4. IN3–IN6 Threshold Settings

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
02h	8002h	[7:0]	IN3 detector threshold (V3) (see equations in the *IN3–IN6* section).
03h	8003h	[7:0]	IN4 detector threshold (V4) (see equations in the *IN3–IN6* section).
04h	8004h	[7:0]	IN5 (MAX6874 only) detector threshold (V5) (see equations in the *IN3–IN6* section).
05h	8005h	[7:0]	IN6 (MAX6874 only) detector threshold (V6) (see equations in the *IN3–IN6* section).
0Dh	800Dh	[1]	IN3 range selection: 0 = +1V to +5.5V range in 20mV increments. 1 = +0.5V to +3.05V range in 10mV increments.
		[2]	IN4 range selection: 0 = +1V to +5.5V range in 20mV increments. 1 = +0.5V to +3.05V range in 10mV increments.
		[3]	IN5 (MAX6874 only) range selection: 0 = +1V to +5.5V range in 20mV increments. 1 = +0.5V to +3.05V range in 10mV increments.
		[4]	IN6 (MAX6874 only) range selection: 0 = +1V to +5.5V range in 20mV increments. 1 = +0.5V to +3.05V range in 10mV increments.
		[5]	Not used.

GPI1–GPI4 (MAX6874)/GPI1–GPI3 (MAX6875)

The GPI1–GPI4 programmable logic inputs control power-supply sequencing (programmable outputs), reset/interrupt signaling, and watchdog functions (see the *Configuring the Watchdog Timer (Registers 3Ch–3Dh)* section). Configure GPI1–GPI4 for active-low or active-high logic (Table 5). GPI1–GPI4 internally pull down to GND through a 10µA current sink.

$\overline{MR}$

The manual reset ($\overline{MR}$) input initiates a reset condition. Register 40h determines the programmable outputs that assert while $\overline{MR}$ is low (Table 6). All affected programmable outputs remain asserted (see the *Programmable Outputs* section) for their PO_ timeout periods after $\overline{MR}$ releases high. An internal 10µA current source pulls $\overline{MR}$ to DBP. Leave $\overline{MR}$ unconnected or connect to DBP if unused. A programmable output cannot depend solely on $\overline{MR}$.

$\overline{MARGIN}$

$\overline{MARGIN}$ allows system-level testing while power supplies exceed the normal ranges. Drive $\overline{MARGIN}$ low to hold the programmable outputs in their state while system-level testing occurs. Leave $\overline{MARGIN}$ unconnected or connect to DBP if unused. An internal 10µA current source pulls $\overline{MARGIN}$ to DBP. The state of each programmable output does not change while $\overline{MARGIN}$ = GND. $\overline{MARGIN}$ overrides $\overline{MR}$ if both assert at the same time.

Programmable Outputs

The MAX6874 features eight programmable outputs while the MAX6875 features five programmable outputs. Program the open-drain outputs as active-high or active-low. During power-up, the programmable outputs pull to GND with an internal 10µA current sink for 1V < V_{ABP} < V_{UVLO}. The programmable outputs remain in their active states until their respective timeout periods (PO_) expire and all of the programmed conditions are met for each output. Any output programmed to depend

Table 5. GPI1–GPI4 Active Logic States

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
3Bh	803Bh	[0]	GPI1. 0 = active low. 1 = active high.
		[1]	GPI2. 0 = active low. 1 = active high.
		[2]	GPI3. 0 = active low. 1 = active high.
		[3]	GPI4 (MAX6874 only). 0 = active low. 1 = active high.

Table 6. Programmable Output Behavior and $\overline{MR}$

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
40h	8040h	[0]	PO1 (MAX6874 only). 0 = PO1 independent of $\overline{MR}$. 1 = PO1 asserts when $\overline{MR}$ = low.
		[1]	PO2 (MAX6874 only). 0 = PO2 independent of $\overline{MR}$. 1 = PO2 asserts when $\overline{MR}$ = low.
		[2]	PO3 (MAX6874)/PO1 (MAX6875). 0 = PO3/PO1 independent of $\overline{MR}$. 1 = PO3/PO1 asserts when $\overline{MR}$ = low.
		[3]	PO4 (MAX6874)/PO2 (MAX6875). 0 = PO4/PO2 independent of $\overline{MR}$. 1 = PO4/PO2 asserts when $\overline{MR}$ = low.
		[4]	PO5 (MAX6874)/PO3 (MAX6875). 0 = PO5/PO3 independent of $\overline{MR}$. 1 = PO5/PO3 asserts when $\overline{MR}$ = low.
		[5]	PO6 (MAX6874)/PO4 (MAX6875). 0 = PO6/PO4 independent of $\overline{MR}$. 1 = PO6/PO4 asserts when $\overline{MR}$ = low.
		[6]	PO7 (MAX6874)/PO5 (MAX6875). 0 = PO7/PO5 independent of $\overline{MR}$. 1 = PO7/PO5 asserts when $\overline{MR}$ = low.
		[7]	PO8 (MAX6874 only). 0 = PO8 independent of $\overline{MR}$. 1 = PO8 asserts when $\overline{MR}$ = low.

Table 7. PO1 (MAX6874 Only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
0Eh	800Eh	[0]	1 = PO1 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO1 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO1 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO1 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO1 assertion depends on IN5 undervoltage threshold (Table 4).
		[5]	1 = PO1 assertion depends on IN6 undervoltage threshold (Table 4).
		[6]	1 = PO1 assertion depends on watchdog (Tables 19 and 20).
		[7]	Must be set to 0.
0Fh	800Fh	[5:0]	Must be set to 0.
		[6]	1 = PO1 assertion depends on GPI1 (Table 5).
		[7]	1 = PO1 assertion depends on GPI2 (Table 5).
10h	8010h	[0]	1 = PO1 assertion depends on GPI3 (Table 5).
		[1]	1 = PO1 assertion depends on GPI4 (Table 5).
		[2]	1 = PO1 assertion depends on PO2 (Table 8).
		[3]	1 = PO1 assertion depends on PO3 (Table 9).
		[4]	1 = PO1 assertion depends on PO4 (Table 10).
		[5]	1 = PO1 assertion depends on PO5 (Table 11).
		[6]	1 = PO1 assertion depends on PO6 (Table 12).
		[7]	1 = PO1 assertion depends on PO7 (Table 13).
11h	8011h	[0]	1 = PO1 assertion depends on PO8 (Table 14).
40h	8040h	[0]	1 = PO1 asserts when $\overline{MR}$ = low (Table 6).

on no condition always remains in its active state (Table 19). An output configured as active-high is considered asserted when that output is logic high. No output can depend solely on $\overline{MR}$.

The voltage monitors generate fault signals (logical 0) to the MAX6874/MAX6875s' logic array when an input voltage is below the programmed undervoltage threshold.

Registers 0Eh through 3Ah and 40h configure each of the programmable outputs. Programmable timing blocks set the PO_ timeout period from 25µs to 1600ms for each programmable output. See register 3Ah (Table 15) to set the active state (active-high or active-low) for each programmable output and Table 16 for timeout periods for each output.

For example, PO3 (MAX6874—Table 9) may depend on the IN1 undervoltage threshold, and the states of GPI1, PO1, and PO2. Write a one to R16h[0], R17h[6], and R18h[3:2] to configure the output as indicated. IN1 must be above the undervoltage threshold (Table 2), GPI1 must be inactive (Table 5), and PO1 (Tables 7 and 15) and PO2 (Table 9) must be in their deasserted states for the output to deassert.

Table 7 only applies to PO1 of the MAX6874. Write a 0 to a bit to make the PO1 output independent of the respective signal (IN1–IN6 thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Table 8. PO2 (MAX6874 Only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
12h	8012h	[0]	1 = PO2 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO2 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO2 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO2 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO2 assertion depends on IN5 undervoltage threshold (Table 4).
		[5]	1 = PO2 assertion depends on IN6 undervoltage threshold (Table 4).
		[6]	1 = PO2 assertion depends on watchdog (Tables 18 and 19).
		[7]	Must be set to 0.
13h	8013h	[5:0]	Must be set to 0.
		[6]	1 = PO2 assertion depends on GPI1 (Table 5).
		[7]	1 = PO2 assertion depends on GPI2 (Table 5).
14h	8014h	[0]	1 = PO2 assertion depends on GPI3 (Table 5).
		[1]	1 = PO2 assertion depends on GPI4 (Table 5).
		[2]	1 = PO2 assertion depends on PO1 (Table 7).
		[3]	1 = PO2 assertion depends on PO3 (Table 9).
		[4]	1 = PO2 assertion depends on PO4 (Table 10).
		[5]	1 = PO2 assertion depends on PO5 (Table 11).
		[6]	1 = PO2 assertion depends on PO6 (Table 12).
		[7]	1 = PO2 assertion depends on PO7 (Table 13).
15h	8015h	[0]	1 = PO2 assertion depends on PO8 (Table 14).
40h	8040h	[1]	1 = PO2 asserts when $\overline{MR}$ = low (Table 6).

Table 8 only applies to PO2 of the MAX6874. Write a 0 to a bit to make the PO2 output independent of the respective signal (IN1–IN6 thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Table 9. PO3 (MAX6874)/PO1 (MAX6875) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
16h	8016h	[0]	1 = PO3/PO1 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO3/PO1 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO3/PO1 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO3/PO1 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO3 (MAX6874 only) assertion depends on IN5 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[5]	1 = PO3 (MAX6874 only) assertion depends on IN6 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[6]	1 = PO3/PO1 assertion depends on watchdog (Tables 18 and 19).
		[7]	Must be set to 0.
17h	8017h	[5:0]	Must be set to 0.
		[6]	1 = PO3/PO1 assertion depends on GPI1 (Table 5).
		[7]	1 = PO3/PO1 assertion depends on GPI2 (Table 5).
18h	8018h	[0]	1 = PO3/PO1 assertion depends on GPI3 (Table 5).
		[1]	1 = PO3/PO1 assertion depends on GPI4 (Table 5).
		[2]	1 = PO3 (MAX6874 only) assertion depends on PO1 (Table 7). Must be set to 0 for the MAX6875.
		[3]	1 = PO3 (MAX6874 only) assertion depends on PO2 (Table 8). Must be set to 0 for the MAX6875.
		[4]	1 = PO3/PO1 assertion depends on PO4 (MAX6874)/PO2 (MAX6875) (Table 10).
		[5]	1 = PO3/PO1 assertion depends on PO5 (MAX6874)/PO3 (MAX6875) (Table 11).
		[6]	1 = PO3/PO1 assertion depends on PO6 (MAX6874)/PO4 (MAX6875) (Table 12).
		[7]	1 = PO3/PO1 assertion depends on PO7 (MAX6874)/PO5 (MAX6875) (Table 13).
1Ch	801Ch	[1:0]	1 = PO3 (MAX6874 only) assertion depends on PO8 (Table 14). Must be set to 0 for the MAX6875.
40h	8040h	[2]	1 = PO3/PO1 asserts when $\overline{MR}$ = low (Table 6).

Table 9 only applies to PO3 of the MAX6874 and PO1 of the MAX6875. Write a 0 to a bit to make the PO3/PO1 output independent of the respective signal (IN_ thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Table 10. PO4 (MAX6874)/PO2 (MAX6875) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
1Dh	801Dh	[0]	1 = PO4/PO2 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO4/PO2 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO4/PO2 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO4/PO2 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO4 (MAX6874 only) assertion depends on IN5 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[5]	1 = PO4 (MAX6874 only) assertion depends on IN6 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[6]	1 = PO4/PO2 assertion depends on watchdog (Tables 18 and 19).
		[7]	Must be set to 0.
1Eh	801Eh	[5:0]	Must be set to 0.
		[6]	1 = PO4/PO2 assertion depends on GPI1 (Table 5).
		[7]	1 = PO4/PO2 assertion depends on GPI2 (Table 5).
1Fh	801Fh	[0]	1 = PO4/PO2 assertion depends on GPI3 (Table 5).
		[1]	1 = PO4/PO2 assertion depends on GPI4 (Table 5).
		[2]	1 = PO4 (MAX6874 only) assertion depends on PO1 (Table 7). Must be set to 0 for the MAX6875.
		[3]	1 = PO4 (MAX6874 only) assertion depends on PO2 (Table 8). Must be set to 0 for the MAX6875.
		[4]	1 = PO4/PO2 assertion depends on PO3 (MAX6874)/PO1 (MAX6875) (Table 9).
		[5]	1 = PO4/PO2 assertion depends on PO5 (MAX6874)/PO3 (MAX6875) (Table 11).
		[6]	1 = PO4/PO2 assertion depends on PO6 (MAX6874)/PO4 (MAX6875) (Table 12).
		[7]	1 = PO4/PO2 assertion depends on PO7 (MAX6874)/PO5 (MAX6875) (Table 13).
23h	8023h	[0]	1 = PO4 (MAX6874 only) assertion depends on PO8 (Table 14). Must be set to 0 for the MAX6875.
40h	8040h	[3]	1 = PO4/PO2 asserts when $\overline{MR}$ = low (Table 6).

Table 10 only applies to PO4 of the MAX6874 and PO2 of the MAX6875. Write a 0 to a bit to make the PO4/PO2 output independent of the respective signal (IN_ thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Table 11. PO5 (MAX6874)/PO3 (MAX6875) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
24h	8024h	[0]	1 = PO5/PO3 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO5/PO3 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO5/PO3 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO5/PO3 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO5 (MAX6874 only) assertion depends on IN5 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[5]	1 = PO5 (MAX6874 only) assertion depends on IN6 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[6]	1 = PO5/PO3 assertion depends on watchdog (Tables 18 and 19).
		[7]	Must be set to 0.
25h	8025h	[5:0]	Must be set to 0.
		[6]	1 = PO5/PO3 assertion depends on GPI1 (Table 5).
		[7]	1 = PO5/PO3 assertion depends on GPI2 (Table 5).
26h	8026h	[0]	1 = PO5/PO3 assertion depends on GPI3 (Table 5).
		[1]	1 = PO5/PO3 assertion depends on GPI4 (Table 5).
		[2]	1 = PO5 (MAX6874 only) assertion depends on PO1 (Table 7). Must be set to 0 for the MAX6875.
		[3]	1 = PO5 (MAX6874 only) assertion depends on PO2 (Table 8). Must be set to 0 for the MAX6875.
		[4]	1 = PO5/PO3 assertion depends on PO3 (MAX6874)/PO1 (MAX6875) (Table 9).
		[5]	1 = PO5/PO3 assertion depends on PO4 (MAX6874)/PO2 (MAX6875) (Table 10).
		[6]	1 = PO5/PO3 assertion depends on PO6 (MAX6874)/PO4 (MAX6875) (Table 12).
		[7]	1 = PO5/PO3 assertion depends on PO7 (MAX6874)/PO5 (MAX6875) (Table 13).
2Ah	802Ah	[0]	1 = PO5 (MAX6874 only) assertion depends on PO8 (Table 14). Must be set to 0 for the MAX6875.
40h	8040h	[4]	1 = PO5/PO3 asserts when $\overline{MR}$ = low (Table 6).

Table 11 only applies to PO5 of the MAX6874 and PO3 of the MAX6875. Write a 0 to a bit to make the PO5/PO3 output independent of the respective signal (IN_ thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Table 12. PO6 (MAX6874)/PO4 (MAX6875) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
2Bh	802Bh	[0]	1 = PO6/PO4 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO6/PO4 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO6/PO4 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO6/PO4 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO6 (MAX6874 only) assertion depends on IN5 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[5]	1 = PO6 (MAX6874 only) assertion depends on IN6 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[6]	1 = PO6/PO4 assertion depends on watchdog (Tables 18 and 19).
		[7]	Must be set to 0.
2Ch	802Ch	[5:0]	Must be set to 0.
		[6]	1 = PO6/PO4 assertion depends on GPI1 (Table 5).
		[7]	1 = PO6/PO4 assertion depends on GPI2 (Table 5).
2Dh	802Dh	[0]	1 = PO6/PO4 assertion depends on GPI3 (Table 5).
		[1]	1 = PO6/PO4 assertion depends on GPI4 (Table 5).
		[2]	1 = PO6 (MAX6874 only) assertion depends on PO1 (Table 7). Must be set to 0 for the MAX6875.
		[3]	1 = PO6 (MAX6874 only) assertion depends on PO2 (Table 8). Must be set to 0 for the MAX6875.
		[4]	1 = PO6/PO4 assertion depends on PO3 (MAX6874)/PO1 (MAX6875) (Table 9).
		[5]	1 = PO6/PO4 assertion depends on PO4 (MAX6874)/PO2 (MAX6875) (Table 10).
		[6]	1 = PO6/PO4 assertion depends on PO5 (MAX6874)/PO3 (MAX6875) (Table 11).
		[7]	1 = PO6/PO4 assertion depends on PO7 (MAX6874)/PO5 (MAX6875) (Table 13).
31h	8031h	[0]	1 = PO6 (MAX6874 only) assertion depends on PO8 (Table 14). Must be set to 0 for the MAX6875.
40h	8040h	[5]	1 = PO6/PO4 asserts when $\overline{MR}$ = low (Table 6).

Table 12 only applies to PO6 of the MAX6874 and PO4 of the MAX6875. Write a 0 to a bit to make the PO6/PO4 output independent of the respective signal (IN_ thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Table 13. PO7 (MAX6874)/PO5 (MAX6875) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
32h	8032h	[0]	1 = PO7/PO5 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO7/PO5 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO7/PO5 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO7/PO5 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO7 (MAX6874 only) assertion depends on IN5 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[5]	1 = PO7 (MAX6874 only) assertion depends on IN6 undervoltage threshold (Table 4). Must be set to 0 for the MAX6875.
		[6]	1 = PO7/PO5 assertion depends on watchdog (Tables 18 and 19).
		[7]	Must be set to 0.
33h	8033h	[5:0]	Must be set to 0.
		[6]	1 = PO7/PO5 assertion depends on GPI1 (Table 5).
		[7]	1 = PO7/PO5 assertion depends on GPI2 (Table 5).
34h	8034h	[0]	1 = PO7/PO5 assertion depends on GPI3 (Table 5).
		[1]	1 = PO7/PO5 assertion depends on GPI4 (Table 5).
		[2]	1 = PO7 (MAX6874 only) assertion depends on PO1 (Table 7). Must be set to 0 for the MAX6875.
		[3]	1 = PO7 (MAX6874 only) assertion depends on PO2 (Table 8). Must be set to 0 for the MAX6875.
		[4]	1 = PO7/PO5 assertion depends on PO3 (MAX6874)/PO1 (MAX6875) (Table 9).
		[5]	1 = PO7/PO5 assertion depends on PO4 (MAX6874)/PO2 (MAX6875) (Table 10).
		[6]	1 = PO7/PO5 assertion depends on PO5 (MAX6874)/PO3 (MAX6875) (Table 11).
		[7]	1 = PO7/PO5 assertion depends on PO6 (MAX6874)/PO4 (MAX6875) (Table 12).
35h	8035h	[0]	1 = PO7 (MAX6874 only) assertion depends on PO8 (Table 14). Must be set to 0 for the MAX6875.
40h	8040h	[6]	1 = PO7 asserts when $\overline{MR}$ = low (Table 6).

Table 13 only applies to PO7 of the MAX6874 and PO5 of the MAX6875. Write a 0 to a bit to make the PO7/PO5 output independent of the respective signal (IN_ thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Table 14. PO8 (MAX6874 only) Output Dependency

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT	OUTPUT ASSERTION CONDITIONS
36h	8036h	[0]	1 = PO8 assertion depends on IN1 undervoltage threshold (Table 2).
		[1]	1 = PO8 assertion depends on IN2 undervoltage threshold (Table 3).
		[2]	1 = PO8 assertion depends on IN3 undervoltage threshold (Table 4).
		[3]	1 = PO8 assertion depends on IN4 undervoltage threshold (Table 4).
		[4]	1 = PO8 assertion depends on IN5 undervoltage threshold (Table 4).
		[5]	1 = PO8 assertion depends on IN6 undervoltage threshold (Table 4).
		[6]	1 = PO8 assertion depends on watchdog (Tables 18 and 19).
		[7]	Must set to 0.
37h	8037h	[5:0]	Must set to 0.
		[6]	1 = PO8 assertion depends on GPI1 (Table 5).
		[7]	1 = PO8 assertion depends on GPI2 (Table 5).
38h	8038h	[0]	1 = PO8 assertion depends on GPI3 (Table 5).
		[1]	1 = PO8 assertion depends on GPI4 (Table 5).
		[2]	1 = PO8 assertion depends on PO1 (Table 7).
		[3]	1 = PO8 assertion depends on PO2 (Table 8).
		[4]	1 = PO8 assertion depends on PO3 (Table 9).
		[5]	1 = PO8 assertion depends on PO4 (Table 10).
		[6]	1 = PO8 assertion depends on PO5 (Table 11).
		[7]	1 = PO8 assertion depends on PO6 (Table 12).
39h	8039h	[0]	1 = PO8 assertion depends on PO7 (Table 13).
40h	8040h	[7]	1 = PO8 asserts when $\overline{MR}$ = low (Table 6).

Table 14 only applies to PO8 of the MAX6874. Write a 0 to a bit to make the PO8 output independent of the respective signal (IN1–IN6 thresholds, WD, GPI1–GPI4, $\overline{MR}$, or other programmable outputs).

Output Stage Configurations

Independently program each programmable output as active-high or active-low (Table 15). All programmable outputs of the MAX6874/MAX6875 are open-drain only. See Table 16 to set the timeout period for each output.

Open-Drain Output Configuration

Connect an external pullup resistor from the programmable output to an external voltage when configured as an open-drain output. PO1–PO4 (PO1 and PO2 for the MAX6875) may be pulled up to +13.2V. PO5–PO8 (PO3–PO5 for the MAX6875) may be pulled up to a voltage less than or equal to ABP. Choose the pullup resistor depending on the number of devices connected to the open-drain output and the allowable current consumption. The open-drain output configuration allows wire-ORed connections, and provides flexibility in setting the pullup current.

Configuring the MAX6874/MAX6875

The MAX6874/MAX6875 factory-default configuration sets all EEPROM registers to 00h except register 3Ah, which is set to FFh. This configuration sets all of the programmable outputs as active-high (putting all outputs into high-impedance states until the device is reconfig-

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Table 15. Programmable Output Active States

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
3Ah	803Ah	[0]	PO1 (MAX6874 only). 0 = active low, 1 = active high.
		[1]	PO2 (MAX6874 only). 0 = active low, 1 = active high.
		[2]	PO3 (MAX6874)/PO1 (MAX6875). 0 = active low, 1 = active high.
		[3]	PO4 (MAX6874)/PO2 (MAX6875). 0 = active low, 1 = active high.
		[4]	PO5 (MAX6874)/PO3 (MAX6875). 0 = active low, 1 = active high.
		[5]	PO6 (MAX6874)/PO4 (MAX6875). 0 = active low, 1 = active high.
		[6]	PO7 (MAX6874)/PO5 (MAX6875). 0 = active low, 1 = active high.
		[7]	PO8 (MAX6874 only). 0 = active low, 1 = active high.

Table 16. PO_ Timeout Periods

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	AFFECTED OUTPUTS		DESCRIPTION
			MAX6874	MAX6875	
11h	8011h	[3:1]	PO1	—	000 = 25µs 001 = 1.5625ms 010 = 6.25ms 011 = 25ms 100 = 50ms 101 = 200ms 110 = 400ms 111 = 1600ms
15h	8015h	[3:1]	PO2	—	
1Ch	801Ch	[4:2]	PO3	PO1	
23h	8023h	[4:2]	PO4	PO2	
2Ah	802Ah	[3:1]	PO5	PO3	
31h	8031h	[3:1]	PO6	PO4	
35h	8035h	[3:1]	PO7	PO5	
39h	8039h	[3:1]	PO8	—	

ured by the user). To configure the MAX6874/ MAX6875, first apply an input voltage to IN1 or one of IN3–IN5 (MAX6874)/IN3–IN4 (MAX6875) (see the *Powering the MAX6874/MAX6875* section). V_{IN1} > +4V or one of V_{IN3}–V_{IN5} > +2.7V, to ensure device operation. Next, transmit data through the serial interface. Use the block write protocol to quickly configure the device. Write to the configuration registers first to ensure the device is configured properly. After completing the setup procedure, use the read word protocol to verify the data from the configuration registers. Lastly, use the write word protocol to write this data to the EEPROM registers. After completing EEPROM register configuration, apply full power to the system to begin normal operation. The nonvolatile EEPROM stores the latest configuration upon removal of power. Write 0's to all EEPROM registers to clear the memory.

Software Reboot

A software reboot allows the user to restore the EEPROM configuration to the volatile registers without cycling the power supplies. Use the send byte command with data byte 88h to initiate a software reboot. The 3.5ms (max) power-up delay also applies after a software reboot.

SMBus/I²C-Compatible Serial Interface

The MAX6874/MAX6875 feature an I²C/SMBus-compatible serial interface consisting of a serial data line (SDA) and a serial clock line (SCL). SDA and SCL allow bidirectional communication between the MAX6874/MAX6875 and the master device at clock rates up to 400kHz. Figure 2 shows the interface timing diagram. The MAX6874/MAX6875 are transmit/receive slave-only devices, relying upon a master device to generate a clock signal. The master device (typically a microcontroller) initiates data transfer on the bus and generates SCL to permit that transfer.

A master device communicates to the MAX6874/MAX6875 by transmitting the proper address followed by command and/or data words. Each transmit sequence is framed by a START (S) or REPEATED START (SR) condition and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge pulse.

SCL is a logic input, while SDA is a logic input/open-drain output. SCL and SDA both require external pullup resistors to generate the logic-high voltage. Use 4.7kΩ for most applications.

Bit Transfer

Each clock pulse transfers one data bit. The data on SDA must remain stable while SCL is high (Figure 3), otherwise the MAX6874/MAX6875 register a START or STOP condition (Figure 4) from the master. SDA and SCL idle high when the bus is not busy.

Start and Stop Conditions

Both SCL and SDA idle high when the bus is not busy. A master device signals the beginning of a transmission with a START (S) condition (Figure 4) by transitioning SDA from high to low while SCL is high. The master device issues a STOP (P) condition (Figure 4) by transitioning SDA from low to high while SCL is high. A STOP condition frees the bus for another transmission. The bus remains active if a REPEATED START condition is generated, such as in the block read protocol (see Figure 7).

Early STOP Conditions

The MAX6874/MAX6875 recognize a STOP condition at any point during transmission except if a STOP condition occurs in the same high pulse as a START condition. This condition is not a legal I^2C format. At least one clock pulse must separate any START and STOP condition.

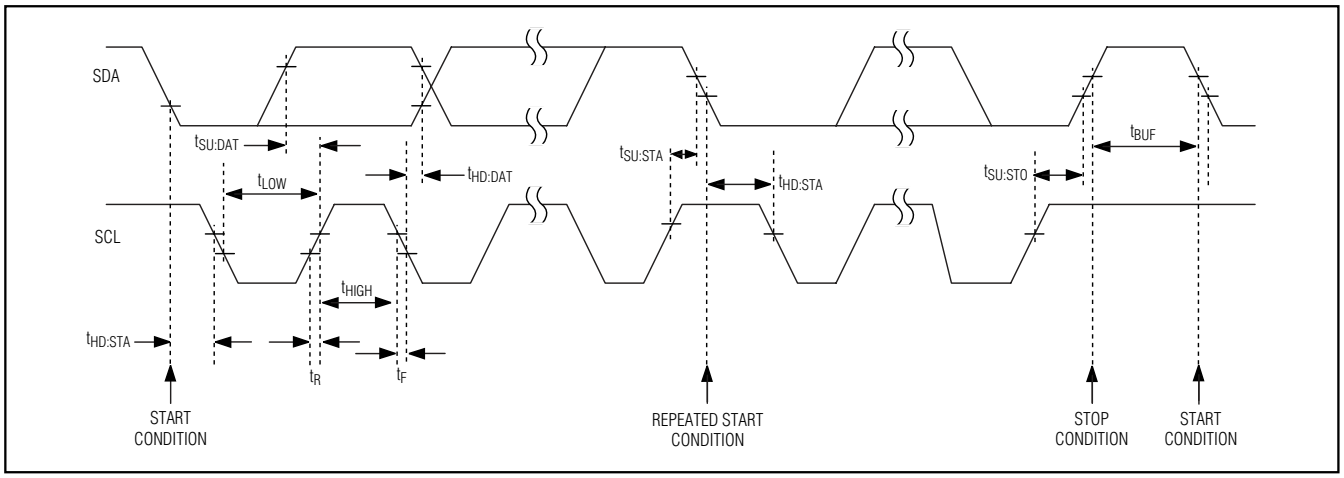

Figure 2. Serial-Interface Timing Details

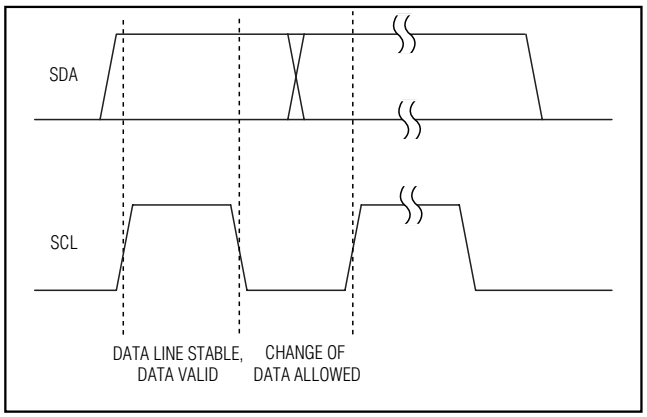

Figure 3. Bit Transfer

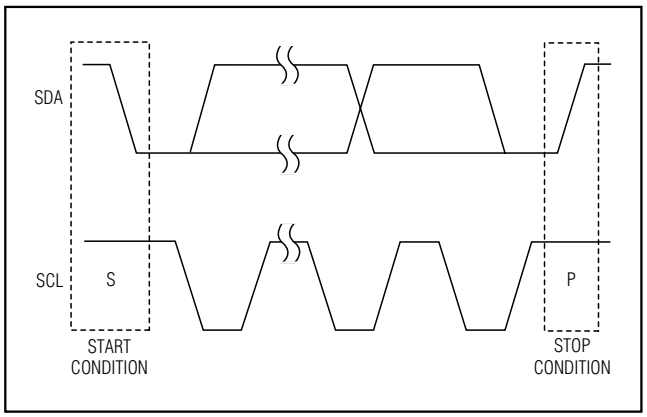

Figure 4. Start and Stop Conditions

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Repeated START Conditions

A REPEATED START (SR) condition may indicate a change of data direction on the bus. Such a change occurs when a command word is required to initiate a read operation (see Figure 7). SR may also be used when the bus master is writing to several I²C devices and does not want to relinquish control of the bus. The MAX6874/MAX6875 serial interface supports continuous write operations with or without an SR condition separating them. Continuous read operations require SR conditions because of the change in direction of data flow.

Acknowledge

The acknowledge bit (ACK) is the 9th bit attached to any 8-bit data word. The receiving device always generates an ACK. The MAX6874/MAX6875 generate an ACK when receiving an address or data by pulling SDA low during the 9th clock period (Figure 5). When transmitting data, such as when the master device reads data back from the MAX6874/MAX6875, the MAX6874/MAX6875 wait for the master device to generate an ACK. Monitoring ACK allows for detection of unsuccessful data transfers. An unsuccessful data transfer occurs if the receiving device is busy or if a system fault has occurred. In the event of an unsuccessful data transfer, the bus master should reattempt communication at a later time. The MAX6874/MAX6875 generate a NACK after the slave address during a software reboot, while writing to the EEPROM, or when receiving an illegal memory address.

Slave Address

The MAX6874 slave address conforms to the following table:

SA7 (MSB)	SA6	SA5	SA4	SA3	SA2	SA1	SA0 (LSB)
1	0	1	0	A1	A0	X	R/$\overline{W}$

X = Don't care.

The MAX6875 slave address conforms to the following table:

SA7 (MSB)	SA6	SA5	SA4	SA3	SA2	SA1	SA0 (LSB)
1	0	1	0	0	A0	X	R/$\overline{W}$

X = Don't care.

SA7 through SA4 represent the standard interface address (1010) for devices with EEPROM. SA3 and SA2 correspond to the A1 and A0 address inputs of the MAX6874/MAX6875 (hardwired as logic low or logic high). A1 is internally set to 0 for the MAX6875. SA0 is a read/write flag bit (0 = write, 1 = read).

The A0 and A1 address inputs allow up to four MAX6874s or two MAX6875s to connect to one bus. Connect A0 and A1 to GND or to the serial interface power supply (see Figure 6).

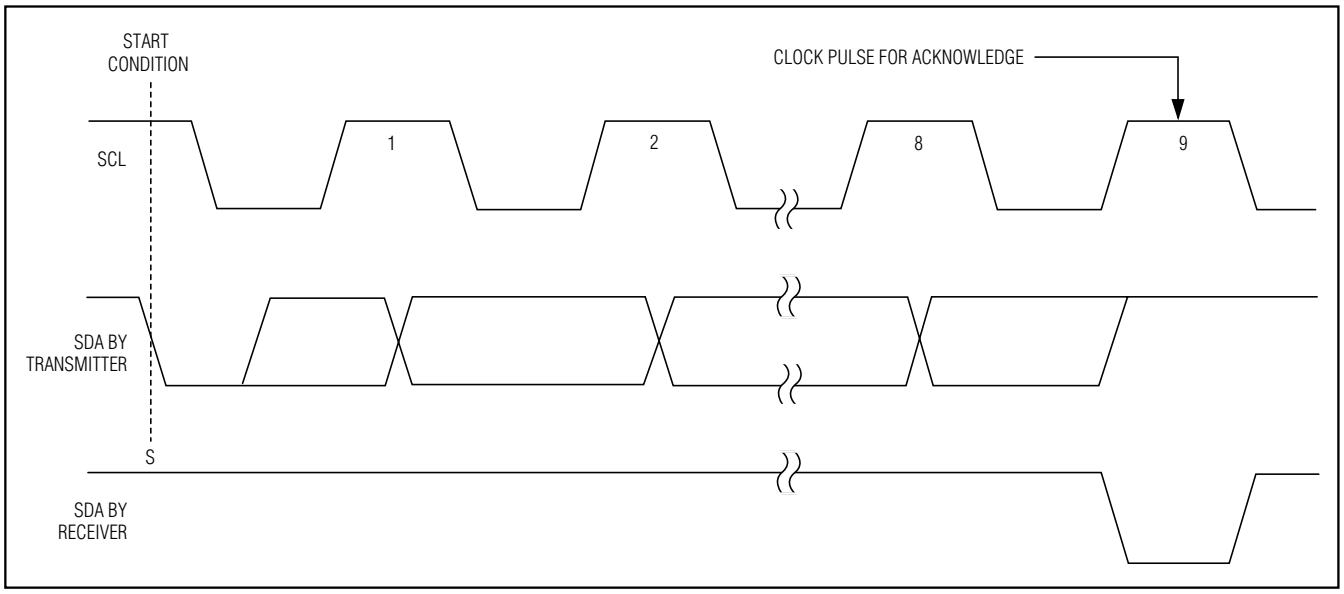

Figure 5. Acknowledge

Send Byte

The send byte protocol allows the master device to send one byte of data to the slave device (see Figure 7). The send byte presets a register pointer address for a subsequent read or write. The slave sends a NACK instead of an ACK if the master tries to send an address that is not allowed. If the master sends 80h, 81h, or 82h, the data is ACK. This could be start of the write byte/word protocol, and the slave expects at least one further data byte. If the master sends a stop condition, the internal address pointer does not change. If the master sends 84h, this signifies that the block read protocol is expected, and a repeated start condition should follow. The device reboots if the master sends 88h. The send byte procedure follows:

1) The master sends a start condition.
2) The master sends the 7-bit slave address and a write bit (low).
3) The addressed slave asserts an ACK on SDA.
4) The master sends an 8-bit data byte.
5) The addressed slave asserts an ACK on SDA.
6) The master sends a stop condition.

Write Byte/Word

The write byte/word protocol allows the master device to write a single byte in the register bank, preset an EEPROM (configuration or user) address for a subsequent read, or to write a single byte to the configuration or user EEPROM (see Figure 7). The write byte/word procedure follows:

1) The master sends a start condition.
2) The master sends the 7-bit slave address and a write bit (low).
3) The addressed slave asserts an ACK on SDA.
4) The master sends an 8-bit command code.
5) The addressed slave asserts an ACK on SDA.
6) The master sends an 8-bit data byte.
7) The addressed slave asserts an ACK on SDA.
8) The master sends a stop condition or sends another 8-bit data byte.
9) The addressed slave asserts an ACK on SDA.
10) The master sends a stop condition.

To write a single byte to the register bank, only the 8-bit command code and a single 8-bit data byte are sent. The command code must be in the range of 00h to 45h. The data byte is written to the register bank if the command code is valid. The slave generates a NACK at step 5 if the command code is invalid.

To preset an EEPROM (configuration or user) address for a subsequent read, the 8-bit command code and a single 8-bit data byte are sent. The command code must be 80h if the write is to be directed into the configuration EEPROM, or 81h or 82h, if the write is to be directed into the user EEPROM. If the command code is 80h, the data byte must be in the range of 00h to 45h. If the command code is 81h or 82h, the data byte can be 00h to FFh. A NACK is generated in step 7 if none of the above conditions are true.

To write a single byte of data to the user or configuration EEPROM, the 8-bit command code and a single 8-bit data byte are sent. The following 8-bit data byte is written to the addressed EEPROM location.

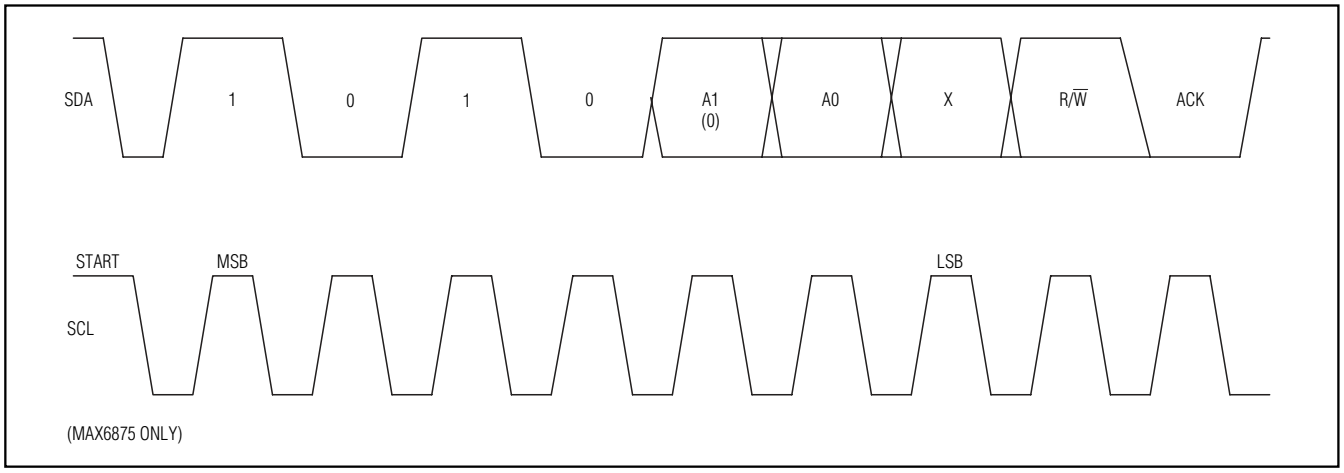

Figure 6. Slave Address

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SEND BYTE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	DATA	ACK	P
	7 bits	0		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Data Byte–presets the internal address pointer.

WRITE WORD FORMAT

S	ADDRESS	$\overline{WR}$	ACK	COMMAND	ACK	DATA	ACK	DATA	ACK	P
	7 bits	0		8 bits		8 bits		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Command Byte–MSB of the EEPROM register being written.

Data Byte–first byte is the LSB of the EEPROM address. Second byte is the actual data.

RECEIVE BYTE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	DATA	$\overline{ACK}$	P
	7 bits	1		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Data Byte–reads data from the register commanded by the last read byte or write byte transmission. Also dependent on a send byte.

WRITE BYTE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	COMMAND	ACK	DATA	ACK	P
	7 bits	0		8 bits		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Command Byte–selects register being written.

Data Byte–data goes into the register set by the command byte if the command is below 50h. If the command is 80h, 81h, or 82h, the data byte presets the LSB of an EEPROM address.

BLOCK WRITE FORMAT

S	ADDRESS	$\overline{WR}$	ACK	COMMAND	ACK	BYTE COUNT= N	ACK	DATA BYTE 1	ACK	DATA BYTE ...	ACK	DATA BYTE N	ACK	P
	7 bits	0		83h		8 bits		8 bits		8 bits		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Command Byte–prepares device for block operation.

Data Byte–data goes into the register set by the command byte.

BLOCK READ FORMAT

S	ADDRESS	$\overline{WR}$	ACK	COMMAND	ACK	SR	ADDRESS	$\overline{WR}$	ACK	BYTE COUNT= 16	ACK	DATA BYTE 1	ACK	DATA BYTE ...	ACK	DATA BYTE N	ACK	P
	7 bits	0		84h			7 bits	1		10h		8 bits		8 bits		8 bits		

Slave Address–equivalent to chip-select line of a 3-wire interface.

Command Byte–prepares device for block operation.

Slave Address–equivalent to chip-select line of a 3-wire interface.

Data Byte–data goes into the register set by the command byte.

S = Start condition.
P = Stop condition.

Shaded = Slave transmission.
SR = Repeated start condition.

Figure 7. SMBus/I²C Protocols

Block Write

The block write protocol allows the master device to write a block of data (1 to 16 bytes) to the EEPROM or to the register bank (see Figure 7). The destination address must already be set by the send byte or write byte protocol and the command code must be 83h. If the number of bytes to be written causes the address pointer to exceed 45h for the configuration register or configuration EEPROM, the address pointer stays at 45h, overwriting this memory address with the remaining bytes of data. The last data byte sent is stored at register address 45h. If the number of bytes to be written exceeds the address pointer FFh for the user EEPROM, the address pointer loops back to 00h, and continues writing bytes until all data is written. The block write procedure follows:

1) The master sends a start condition.
2) The master sends the 7-bit slave address and a write bit (low).
3) The addressed slave asserts an ACK on SDA.
4) The master sends the 8-bit command code for block write (83h).
5) The addressed slave asserts an ACK on SDA.
6) The master sends the 8-bit byte count (1 to 16 bytes) N.
7) The addressed slave asserts an ACK on SDA.
8) The master sends 8 bits of data.
9) The addressed slave asserts an ACK on SDA.
10) Repeat steps 8 and 9 one time.
11) The master generates a stop condition.

Receive Byte

The receive byte protocol allows the master device to read the register content of the MAX6874/MAX6875 (see Figure 7). The EEPROM or register address must be preset with a send byte or write word protocol first. Once the read is complete, the internal pointer increases by one. Repeating the receive byte protocol reads the contents of the next address. The receive byte procedure follows:

1) The master sends a start condition.
2) The master sends the 7-bit slave address and a read bit (high).
3) The addressed slave asserts an ACK on SDA.
4) The slave sends 8 data bits.
5) The master asserts a NACK on SDA.
6) The master generates a stop condition.

Block Read

The block read protocol allows the master device to read a block of 16 bytes from the EEPROM or register bank (see Figure 7). Read fewer than 16 bytes of data by issuing an early STOP condition from the master, or by generating a NACK with the master. The send byte or write byte protocol predetermines the destination address with a command code of 84h. The block read procedure follows:

1) The master sends a start condition.
2) The master sends the 7-bit slave address and a write bit (low).
3) The addressed slave asserts an ACK on SDA.
4) The master sends 8 bits of the block read command (84h).
5) The slave asserts an ACK on SDA, unless busy.
6) The master generates a repeated start condition.
7) The master sends the 7-bit slave address and a read bit (high).
8) The slave asserts an ACK on SDA.
9) The slave sends the 8-bit byte count (16).
10) The master asserts an ACK on SDA.
11) The slave sends 8 bits of data.
12) The master asserts an ACK on SDA.
13) Repeat steps 8 and 9 fifteen times.
14) The master generates a stop condition.

Address Pointers

Use the send byte protocol to set the register address pointers before read and write operations. For the configuration registers, valid address pointers range from 00h to 45h. Register addresses outside of this range result in a NACK being issued from the MAX6874/MAX6875. When using the block write protocol, the address pointer automatically increments after each data byte, except when the address pointer is already at 45h. If the address pointer is already 45h, and more data bytes are being sent, these subsequent bytes overwrite address 45h repeatedly, leaving only the last data byte sent stored at this register address.

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For the configuration EEPROM, valid address pointers range from 8000h to 8045h. Registers 8046h to 804Fh are reserved and should not be overwritten. Register addresses from 8050h to 80FFh return a NACK from the MAX6874/MAX6875. When using the block write protocol, the address pointer automatically increments after each data byte, except when the address pointer is already at 8045h. If the address pointer is already 8045h, and more data bytes are being sent, these subsequent bytes overwrite address 8045h repeatedly, leaving only the last data byte sent stored at this register address.

For the user EEPROM, valid address pointers range from 8100h to 81FFh and 8200h to 82FFh. Block write and block read protocols allow the address pointer to reset (to 8100h or 8200h) when attempting to write or read beyond 81FFh or 82FFh.

Configuration EEPROM

The configuration EEPROM addresses range from 8000h to 8045h. Write data to the configuration EEPROM to automatically set up the MAX6874/MAX6875 upon power-up. Data transfers from the configuration EEPROM to the configuration registers when ABP exceeds UVLO during power-up or after a software reboot. After ABP exceeds UVLO, an internal 1MHz clock starts after a 5µs delay, and data transfer begins. Data transfer disables access to the configuration registers and EEPROM. The data transfer from EEPROM to configuration registers takes 3.5ms (max). Read configuration EEPROM data at any time after power-up or software reboot. Write commands to the configuration EEPROM are allowed at any time after power-up or software reboot, unless the configuration lock bit is set (see Table 20). The maximum cycle time to write a single byte is 11ms (max).

User EEPROM

The 512 byte user EEPROM addresses range from 8100h to 82FFh (see Figure 7). Store software-revision data, board-revision data, and other data in these registers. The maximum cycle time to write a single byte is 11ms (max).

Configuration Register Bank and EEPROM

The configuration registers can be directly modified by the serial interface without modifying the EEPROM after the power-up procedure terminates and the configuration EEPROM data has been loaded into the configuration register bank. Use the write byte or block write protocols to write directly to the configuration registers. Changes to the configuration registers take effect immediately and are lost upon power removal.

At device power-up, the register bank loads configuration data from the EEPROM. Configuration data may be directly altered in the register bank during application development, allowing maximum flexibility. Transfer the new configuration data, byte by byte, to the configuration EEPROM with the write byte protocol. The next device power-up or software reboot automatically loads the new configuration.

Table 17. Register Map

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	READ/ WRITE	DESCRIPTION
00h	8000h	R/W	IN1 undervoltage detector threshold (Table 2).
01h	8001h	R/W	IN2 undervoltage detector threshold (Table 3).
02h	8002h	R/W	IN3 undervoltage detector threshold (Table 4).
03h	8003h	R/W	IN4 undervoltage detector threshold (Table 4).
04h	8004h	R/W	IN5 undervoltage detector threshold (MAX6874 only) (Table 4).
05h	8005h	R/W	IN6 undervoltage detector threshold (MAX6874 only) (Table 4).
06h	8006h	—	Not used.
07h	8007h	—	Not used.
08h	8008h	—	Not used.
09h	8009h	—	Not used.
0Ah	800Ah	—	Not used.

Table 17. Register Map (continued)

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	READ/ WRITE	DESCRIPTION
0Bh	800Bh	—	Not used.
0Ch	800Ch	—	Not used.
0Dh	800Dh	R/W	Threshold range selection (Tables 2–4).
0Eh	800Eh	R/W	PO1 (MAX6874 only) input selection (Table 7).
0Fh	800Fh	R/W	PO1 (MAX6874 only) input selection (Table 7).
10h	8010h	R/W	PO1 (MAX6874 only) input selection (Table 7).
11h	8011h	R/W	PO1 (MAX6874 only) input selection, PO_ timeout period, and output type selection (Tables 7, 16).
12h	8012h	R/W	PO2 (MAX6874 only) input selection (Table 8).
13h	8013h	R/W	PO2 (MAX6874 only) input selection (Table 8).
14h	8014h	R/W	PO2 (MAX6874 only) input selection (Table 8).
15h	8015h	R/W	PO2 (MAX6874 only) input selection and PO_ timeout period (Tables 8, 16).
16h	8016h	R/W	PO3 (MAX6874)/PO1 (MAX6875) input selection (Table 9).
17h	8017h	R/W	PO3 (MAX6874)/PO1 (MAX6875) input selection (Table 9).
18h	8018h	R/W	PO3 (MAX6874)/PO1 (MAX6875) input selection (Table 9).
19h	8019h	R/W	Set to 0.
1Ah	801Ah	R/W	Set to 0.
1Bh	801Bh	R/W	Set to 0.
1Ch	801Ch	R/W	PO3 (MAX6874)/PO1 (MAX6875) input selection and PO_ timeout period (Tables 9, 16).
1Dh	801Dh	R/W	PO4 (MAX6874)/PO2 (MAX6875) input selection (Table 10).
1Eh	801Eh	R/W	PO4 (MAX6874)/PO2 (MAX6875) input selection (Table 10).
1Fh	801Fh	R/W	PO4 (MAX6874)/PO2 (MAX6875) input selection (Table 10).
20h	8020h	R/W	Set to 0.
21h	8021h	R/W	Set to 0.
22h	8022h	R/W	Set to 0.
23h	8023h	R/W	PO4 (MAX6874)/PO2 (MAX6875) input selection and PO_ timeout period (Tables 6, 18).
24h	8024h	R/W	PO5 (MAX6874)/PO3 (MAX6875) input selection (Table 11).
25h	8025h	R/W	PO5 (MAX6874)/PO3 (MAX6875) input selection (Table 11).
26h	8026h	R/W	PO5 (MAX6874)/PO3 (MAX6875) input selection (Table 11).
27h	8027h	R/W	Set to 0.
28h	8028h	R/W	Set to 0.
29h	8029h	R/W	Set to 0.
2Ah	802Ah	R/W	PO5 (MAX6874)/PO3 (MAX6875) input selection and PO_ timeout period (Tables 11, 18).
2Bh	802Bh	R/W	PO6 (MAX6874)/PO4 (MAX6875) input selection (Table 12).
2Ch	802Ch	R/W	PO6 (MAX6874)/PO4 (MAX6875) input selection (Table 12).

Table 17. Register Map (continued)

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	READ/ WRITE	DESCRIPTION
2Dh	802Dh	R/W	PO6 (MAX6874)/PO4 (MAX6875) input selection (Table 12).
2Eh	802Eh	R/W	Set to 0.
2Fh	802Fh	R/W	Set to 0.
30h	8030h	R/W	Set to 0.
31h	8031h	R/W	PO6 (MAX6874)/PO4 (MAX6875) input selection and PO_ reset timeout period (Tables 12, 16).
32h	8032h	R/W	PO7 (MAX6874)/PO5 (MAX6875) input selection (Table 13).
33h	8033h	R/W	PO7 (MAX6874)/PO5 (MAX6875) input selection (Table 13).
34h	8034h	R/W	PO7 (MAX6874)/PO5 (MAX6875) input selection (Table 13).
35h	8035h	R/W	PO7 (MAX6874)/PO5 (MAX6875) input selection and PO_ timeout period (Tables 13, 16).
36h	8036h	R/W	PO8 (MAX6874 only) input selection (Table 14).
37h	8037h	R/W	PO8 (MAX6874 only) input selection (Table 14).
38h	8038h	R/W	PO8 (MAX6874 only) input selection (Table 14).
39h	8039h	R/W	PO8 (MAX6874 only) input selection and PO_ timeout period (Tables 14, 16).
3Ah	803Ah	R/W	Programmable output polarity (active high/active low) (Table 15).
3Bh	803Bh	R/W	GPI_ input polarity, PO5, PO6 (Table 5).
3Ch	803Ch	R/W	WD input selection and timeout enable (Table 18).
3Dh	803Dh	R/W	WD initial and normal timeout duration (Table 19).
3Eh	803Eh	R/W	Must be set to 0.
3Fh	803Fh	R/W	Must be set to 0.
40h	8040h	R/W	$\overline{MR}$ input and programmable output behavior (Table 6).
41h	8041h	R/W	Must be set to 0.
42h	8042h	R/W	Must be set to 0.
43h	8043h	R/W	User EEPROM write disable (Table 21).
44h	8044h	—	Reserved. Should not be overwritten.
45h	8045h	R/W	Configuration lock (Table 20).

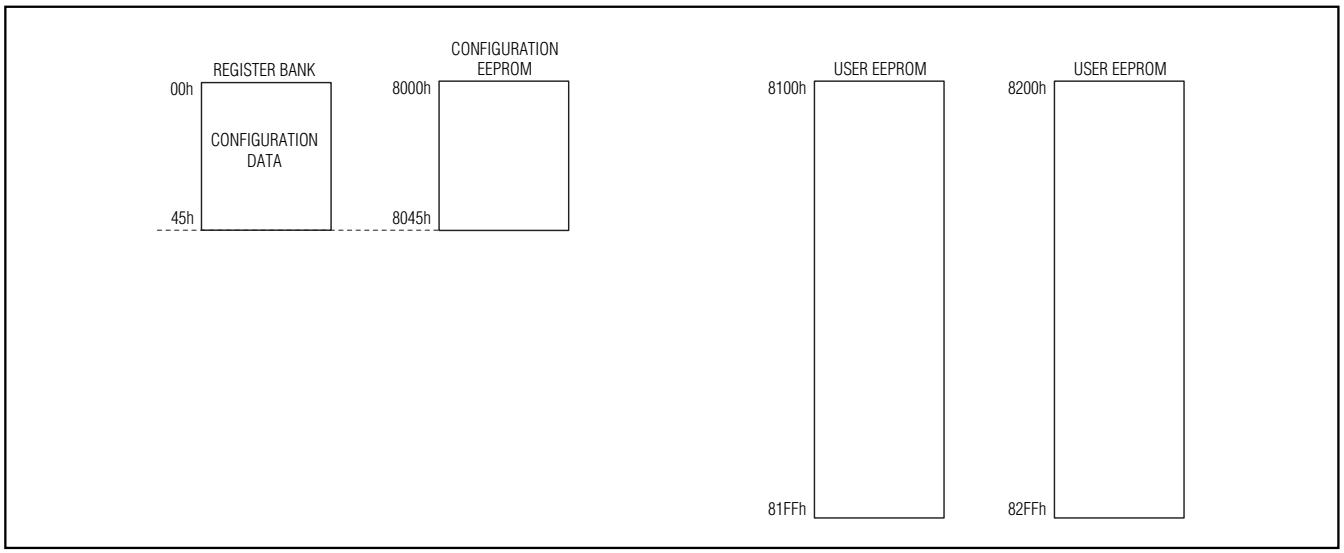


Figure 8. Memory Map

Table 18. Watchdog Inputs

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
3Ch	803Ch	[1:0]	Watchdog Input Selection: 00 = GPI1 01 = GPI2 10 = GPI3 11 = GPI4 (MAX6874 only)
		[4:2]	Watchdog Internal Input Selection: 000 = PO1 (MAX6874), not used (MAX6875) 001 = PO2 (MAX6874), not used (MAX6875) 010 = PO3 (MAX6874), PO1 (MAX6875) 011 = PO4 (MAX6874), PO2 (MAX6875) 100 = PO5 (MAX6874), PO3 (MAX6875) 101 = PO6 (MAX6874), PO4 (MAX6875) 110 = PO7 (MAX6874), PO5 (MAX6875) 111 = PO8 (MAX6874), not used (MAX6875)
		[6:5]	Watchdog Dependency on Inputs: 00 = 11 = Watchdog clear depends on both GPI_ from 3Ch[1:0] and PO_ from 3Ch[4:2]. 01 = Watchdog clear depends only on PO_ from 3Ch[4:2]. 10 = Watchdog clear depends only on GPI_ from 3Ch[1:0].
		[7]	Must be set to 1

Table 19. Watchdog Timeout Period Selection

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
3Dh	803Dh	[2:0]	Normal Watchdog Timeout Period: 000 = 6.25ms 001 = 25ms 010 = 100ms 011 = 400ms 100 = 1.6s 101 = 6.4s 110 = 25.6s 111 = 102.4s
		[5:3]	Initial Watchdog Timeout Period (immediately following power-up, reset event, or enabling watchdog): 000 = 6.25ms 001 = 25ms 010 = 100ms 011 = 400ms 100 = 1.6s 101 = 6.4s 110 = 25.6s 111 = 102.4s
		[6]	Watchdog Enable: 0 = Disables watchdog timer 1 = Enables watchdog timer
		[7]	Not used

Configuring the Watchdog Timer (Registers 3Ch–3Dh)

A watchdog timer monitors microprocessor (µP) software execution for a stalled condition and resets the µP if it stalls. The output of a watchdog timer (one of the programmable outputs) connects to the reset input or a nonmaskable interrupt of the µP.

Registers 3Ch–3Dh configure the watchdog functionality of the MAX6874/MAX6875. Program the watchdog timer to assert one or more programmable outputs (see Tables 7–14). Program the watchdog timer to reset on one of the GPI_ inputs, one of the programmable outputs, or a combination of one GPI_ input and one programmable output.

The watchdog timer features independent initial and normal watchdog timeout periods. The initial watchdog timeout period applies immediately after power-up, after a reset event takes place, or after enabling the watchdog timer. The initial watchdog timeout period allows the µP to perform its initialization process. If no pulse occurs during the initial watchdog timeout period, the µP is taking too long to initialize, indicating a potential problem.

The normal watchdog timeout period applies in every other cycle after the initial watchdog timeout period occurs. The normal watchdog timeout period monitors a pulsed output of the µP that indicates when normal processor behavior occurs. If no pulse occurs during the normal watchdog timeout period, this indicates that the processor has stopped operating or is stuck in an infinite execution loop.

Register 3Dh programs the initial and normal watchdog timeout periods, and enables or disables the watchdog timer. See Tables 18 and 19 for a summary of the watchdog behavior.

Configuration Lock

Lock the configuration register bank and configuration EEPROM contents after initial programming by setting the lock bit high (see Table 20). Locking the configuration prevents write operations to all registers except the configuration lock register. Clear the lock bit to reconfigure the device.

Table 20. Configuration Lock Register

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
45h	8045h	[0]	0 = configuration unlocked. 1 = configuration locked.
		[7:1]	Not used.

Table 21. Write Disable Register

REGISTER ADDRESS	EEPROM MEMORY ADDRESS	BIT RANGE	DESCRIPTION
43h	8043h	[0]	0 = write not disabled if PO1 asserts (MAX6874). 1 = write disabled if PO1 asserts (MAX6874). Set to 0 (MAX6875).
		[1]	0 = write not disabled if PO2 asserts (MAX6874). 1 = write disabled if PO2 asserts (MAX6874). Set to 0 (MAX6875).
		[2]	0 = write not disabled if PO3 (MAX6874)/PO1 (MAX6875) asserts. 1 = write disabled if PO3 (MAX6874)/PO1 (MAX6875) asserts.
		[3]	0 = write not disabled if PO4 (MAX6874)/PO2 (MAX6875) asserts. 1 = write disabled if PO4 (MAX6874)/PO2 (MAX6875) asserts.
		[4]	0 = write not disabled if PO5 (MAX6874)/PO3 (MAX6875) asserts. 1 = write disabled if PO5 (MAX6874)/PO3 (MAX6875) asserts.
		[5]	0 = write not disabled if PO6 (MAX6874)/PO4 (MAX6875) asserts. 1 = write disabled if PO6 (MAX6874)/PO4 (MAX6875) asserts.
		[6]	0 = write not disabled if PO7 (MAX6874)/PO5 (MAX6875) asserts. 1 = write disabled if PO7 (MAX6874)/PO5 (MAX6875) asserts.
		[7]	0 = write not disabled if PO8 asserts (MAX6874). 1 = write disabled if PO8 asserts (MAX6874). Set to 0 (MAX6875).

Write Disable

A unique write disable feature protects the MAX6874/MAX6875 from inadvertent user EEPROM writes. As input voltages that power the serial interface, a µP, or any other writing devices fall, unintentional data may be written onto the data bus. The user EEPROM write disable function (see Table 21) ensures that unintentional data does not corrupt the MAX6874/MAX6875 EEPROM data.

Applications Information

Configuration Download at Power-up

The configuration of the MAX6874/MAX6875 (undervoltage thresholds, PO_ timeout periods, watchdog behavior, programmable output conditions, etc.) depends on the contents of the EEPROM. The EEPROM is comprised of buffered latches that store the configuration. The local volatile memory latches lose their contents at power-down. Therefore, at power-up, the device configuration must be restored by downloading the contents of the EEPROM (non-volatile memory) to the local latches. This download occurs in a number of steps:

1) Programmable outputs go high impedance with no power applied to the device.
2) When ABP exceeds +1V, all programmable outputs are weakly pulled to GND through a 10µA current sink.
3) When ABP exceeds UVLO, the configuration EEPROM starts to download its contents to the volatile configuration registers. The programmable outputs assume their programmed conditional output state when download is complete.

EEPROM-Programmable, Hex/Quad, Power-Supply Sequencers/Supervisors

4) Any attempt to communicate with the device prior to this download completion results in a NACK being issued from the MAX6874/MAX6875.

Forcing Programmable Outputs High During Power-Up

A weak 10µA pulldown holds all programmable outputs low during power-up until ABP exceeds the undervoltage lockout (UVLO) threshold. Applications requiring a guaranteed high programmable output for ABP down to GND require external pullup resistors to maintain the logic state until ABP exceeds UVLO. Use 20kΩ resistors for most applications.

Uses for General-Purpose Inputs (GPI1–GPI4)

Watchdog Timer

Program GPI_ as an input to the watchdog timer in the MAX6874/MAX6875. The GPI_ input must toggle within the watchdog timeout period, otherwise any programmable output dependent on the watchdog timer asserts.

Additional Manual Reset Functions

Program PO7 (MAX6874)/PO5 (MAX6875) to depend on one of the GPI_ inputs. Any output that depends on GPI_ asserts when GPI_ is held in its active state, effectively acting as a manual reset input.

Other Fault Signals from µC

Connect a general-purpose output from a µC to one of the GPI_ inputs to allow interrupts to assert any output of the MAX6874/MAX6875. Configure one of the programmable outputs to assert on whichever GPI_ input connects to the general purpose output of the µC.

Layout and Bypassing

For better noise immunity, bypass each of the voltage detector inputs to GND with 0.1µF capacitors installed as close to the device as possible. Bypass ABP and DBP to GND with 1µF capacitors installed as close to the device as possible. ABP and DBP are internally generated voltages and should not be used to supply power to external circuitry.

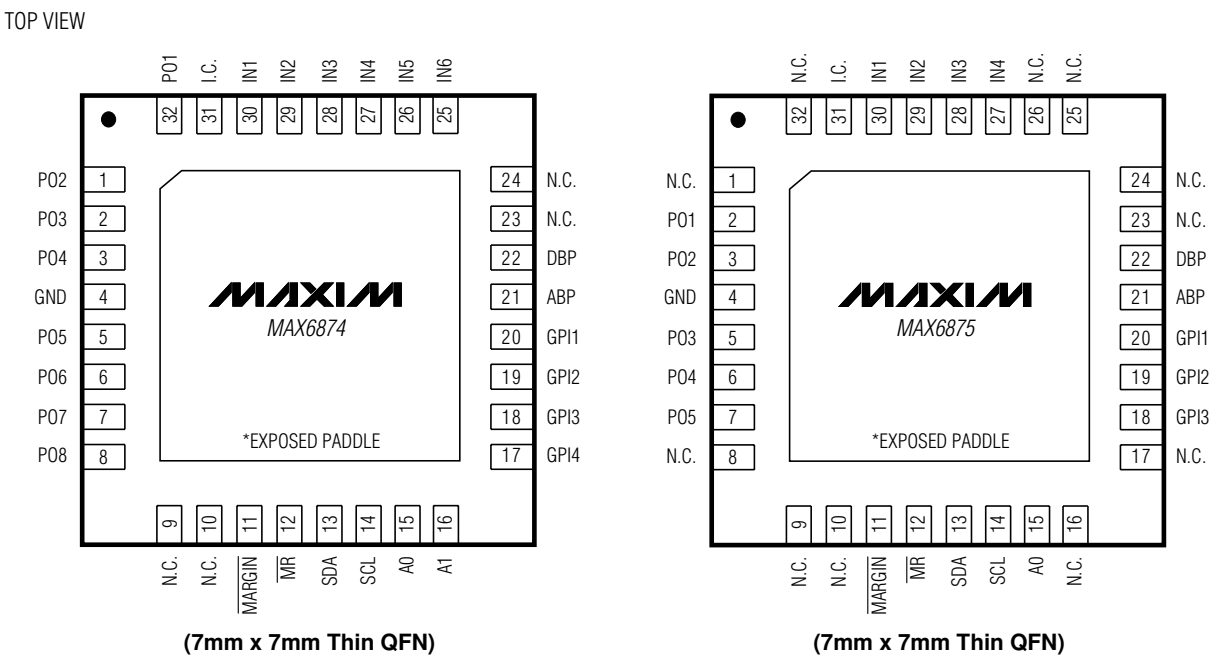
Configuration Latency Period

A delay of less than 5µs occurs between writing to the configuration registers and the time when these changes actually take place, except when changing one of the voltage-detector thresholds. Changing a voltage-detector threshold typically takes 150µs. When changing EEPROM contents, a software reboot or cycling of power is required for these changes to transfer to volatile memory.

Chip Information

PROCESS: BiCMOS

Pin Configurations



*EXPOSED PADDLE INTERNALLY CONNECTED TO GND.

Selector Guide

PART	VOLTAGE-DETECTOR INPUTS	GENERAL-PURPOSE INPUTS	PROGRAMMABLE OUTPUTS
MAX6874ETJ	6	4	8
MAX6875ETJ	4	3	5

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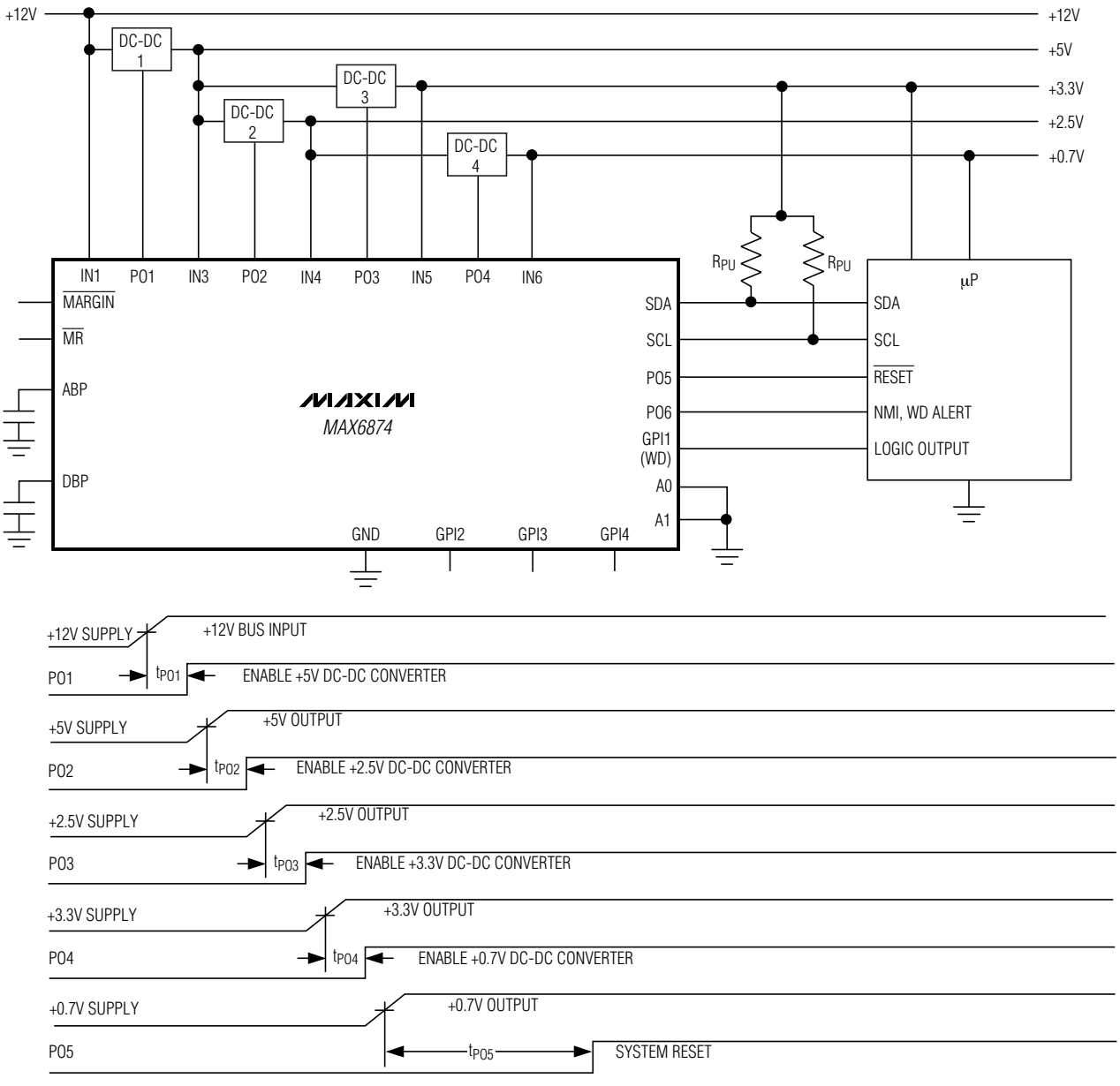
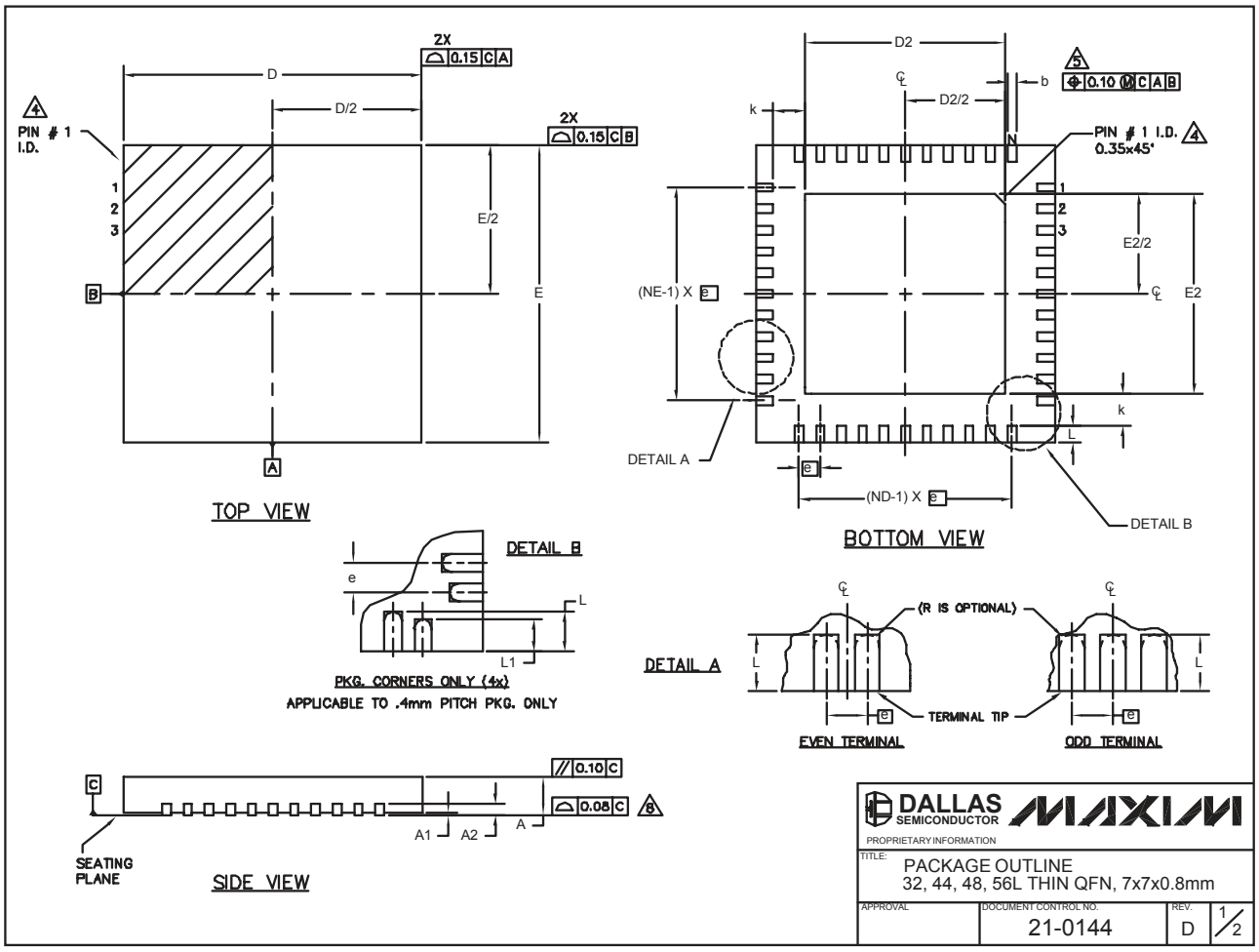
Typical Operating Circuit



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)

32, 44, 48L QFN.EPS



EEPROM-Programmable, Hex/Quad, Power-Supply Sequencers/Supervisors

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)

COMMON DIMENSIONS

PKG	32L 7x7			44L 7x7			48L 7x7			CUSTOM PKG. (T4877-1) 48L 7x7			56L 7x7		
SYMBOL	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80
A1	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	–	0.05
A2	0.20 REF.			0.20 REF.			0.20 REF.			0.20 REF.			0.20 REF.		
b	0.25	0.30	0.35	0.20	0.25	0.30	0.20	0.25	0.30	0.20	0.25	0.30	0.15	0.20	0.25
D	6.90	7.00	7.10	6.90	7.00	7.10	6.90	7.00	7.10	6.90	7.00	7.10	6.90	7.00	7.10
E	6.90	7.00	7.10	6.90	7.00	7.10	6.90	7.00	7.10	6.90	7.00	7.10	6.90	7.00	7.10
e	0.65 BSC.			0.50 BSC.			0.50 BSC.			0.50 BSC.			0.40 BSC.		
k	0.25	–	–	0.25	–	–	0.25	–	–	0.25	–	–	0.25	0.35	0.45
L	0.45	0.55	0.65	0.45	0.55	0.65	0.30	0.40	0.50	0.45	0.55	0.65	0.40	0.50	0.60
L1	–	–	–	–	–	–	–	–	–	–	–	–	0.30	0.40	0.50
N	32			44			48			44			56		
ND	8			11			12			10			14		
NE	8			11			12			12			14		

EXPOSED PAD VARIATIONS

PKG. CODES	DEPOPULATED LEADS	D2			E2			JEDEC MO220 REV. C	DOWN BONDS ALLOWED
		MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
T3277-1	–	4.55	4.70	4.85	4.55	4.70	4.85	–	NO
T3277-2	–	4.55	4.70	4.85	4.55	4.70	4.85	–	YES
T4477-1	–	4.55	4.70	4.85	4.55	4.70	4.85	WKKD-1	NO
T4477-2	–	4.55	4.70	4.85	4.55	4.70	4.85	WKKD-1	YES
T4477-3	–	4.55	4.70	4.85	4.55	4.70	4.85	WKKD-1	YES
T4877-1**	13,24,37,48	4.20	4.30	4.40	4.20	4.30	4.40	–	NO
T4877-2	–	5.45	5.60	5.63	5.45	5.60	5.63	–	NO
T4877-3	–	4.95	5.10	5.25	4.95	5.10	5.25	–	YES
T4877-4	–	5.45	5.60	5.63	5.45	5.60	5.63	–	YES
T4877-5	–	2.40	2.50	2.60	2.40	2.50	2.60	–	NO
T4877-6	–	5.45	5.60	5.63	5.45	5.60	5.63	–	NO
T5677-1	–	5.20	5.30	5.40	5.20	5.30	5.40	–	YES

** NOTE: T4877-1 IS A CUSTOM 48L PKG. WITH 4 LEADS DEPOPULATED. TOTAL NUMBER OF LEADS ARE 44.

NOTES:

1. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
2. ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
3. N IS THE TOTAL NUMBER OF TERMINALS.
4. THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.
5. DIMENSION b APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
6. ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
7. DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
8. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
9. DRAWING CONFORMS TO JEDEC MO220 EXCEPT THE EXPOSED PAD DIMENSIONS OF T3277-1; T4877-1/-2/-3/-4/-5/-6 & T5677-1.
10. WARPAGE SHALL NOT EXCEED 0.10 mm.

DALLAS SEMICONDUCTOR MAXIM

PROPRIETARY INFORMATION

TITLE:			
PACKAGE OUTLINE 32, 44, 48, 56L THIN QFN, 7x7x0.8mm			
APPROVAL	DOCUMENT CONTROL NO.	REV.	
	21-0144	D	2/2